## o ICOM

# SERVICE MANUAL

# UHF TRANSCEIVER

Icom Inc.

### SCOPE OF THE SERVICE MANUAL

This service manual covers all service information related to the theoretical, physical, mechanical and electrical characteristics of the IC-U18 UHF TRANSCEIVER.

### ASSISTANCE

If you require assistance or further information regarding the operation and capabilities of the IC-U18, contact your nearest authorized Icom Dealer or Icom Service Center.

Address are provided on the back cover for your convenience.

### ORDERING REPLACEMENT PARTS

For the fastest service, supply all of the following information when ordering parts from your dealer or Icom Service Center:

- 1. Equipment model and serial number
- 2. Schematic part identifier or service manual page number
- Unit name and printed circuit board number (e.g., MAIN UNIT/B-1665C)
- Component part number and name (e.g., 2SC2712 Transistor)
- 5. Order number for mechanical parts
- 6. Quantity required (e.g., 3pcs.)



### **REPAIR NOTE**

- DO NOT open transceiver covers until the transceiver is disconnected from a power source.
- DO NOT force any of the variable components. Turn them slowly and smoothly.
- 3. DO NOT short any circuits or electronic parts.
- 4. An insulated tuning tool MUST BE used for all adjustments.
- DO NOT keep power ON for a long time when the transceiver is defective.
- DO NOT transmit power into a signal generator or sweep generator. Always connect a 30dB or 40dB attenuator between the transceiver and a deviation meter or spectrum analyzer when using such test equipment.
- Read the instructions of test equipment thoroughly before connecting the equipment to the transceiver.

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To program the operating frequency, tone frequency, etc., see the separately available EX-704 PROGRAMMING MANUAL (A-8011-1EX).

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#### SECTION 1 **SPECIFICATIONS**

#### GENERAL

- Frequency range
- Type of emission
- Number of channels
- Frequency stability
- Antenna impedance
- Power supply voltage

• Usable temperature range

- : 450~470 MHz
- 16K0F3E :
- : Up to 16 channels
- : ±0.0005%

.

: 50Ω unbalanced

BATTERY PACK	VOLTAGE
CM-71	7.2V
CM-72	8.4V
CM-73	13.2V

#### (Negative ground)

 $-30^{\circ}C \sim +60^{\circ}C (-22^{\circ}F \sim +140^{\circ}F)$ 1

Dimensions

: 65 mm (W) × 109 mm (H) × 35 mm (D) 2.6"(W) × 4.3"(H) × 1.4"(D) : 350g (0.77 lbs.), (without battery pack)

Weight

#### **TRANSMITTER**

• RF Output power (At 13.2V DC) : 5W/1.5W Modulation system : Variable reactance frequency modulation • Current drain (At 13.2V DC) : High power 2.0A Low power 1.5A Microphone impedance : 2.2kΩ : ±5kHz Maximum deviation • Spurious emissions : -60dB : 40dB • FM hum and noise : +1dB, -3dB of +6dB/octave from 300Hz~3000Hz Audio response

: Double superheterodyne

: 0.28µV at 12dB SINAD

2nd 455kHz

: ±7kHz

#### RECEIVER

- Receiver system
- Sensitivity
- Squelch sensitivity (Threshold) : 0.22µV
- Modulation acceptance
- Intermediate frequencies : 1st 23.15MHz
- Current drain (At 13.2V DC)
- Audio output power

:	Audio max. 0.25A Standby 70mA	
:	BATTERY PACK	OUTPUT (at 5% distortion with 8Ω load)
	CM-71	200 mW
	CM-72	350 mW
	CM-73	500 mW

- Audio output impedance
- 8Ω : : 70dB

: : 68dB

70dB 65dB

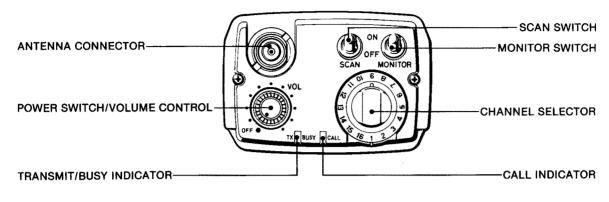
: 40dB

- Selectivity (±25kHz) • Spurious frequency rejection :
- Image rejection
- Inter modulation
- Hum and noise
- Audio response
- : +1dB~-3dB of -6dB/octave from 300Hz~3000Hz
  - 1 1

### SECTION 2 OUTSIDE AND INSIDE VIEWS

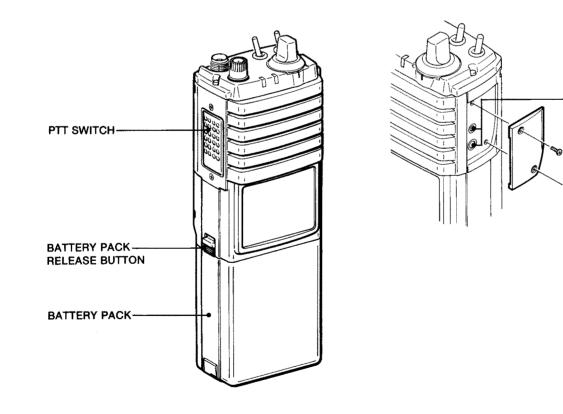
#### 2-1 OUTSIDE VIEWS

#### • TOP VIEW



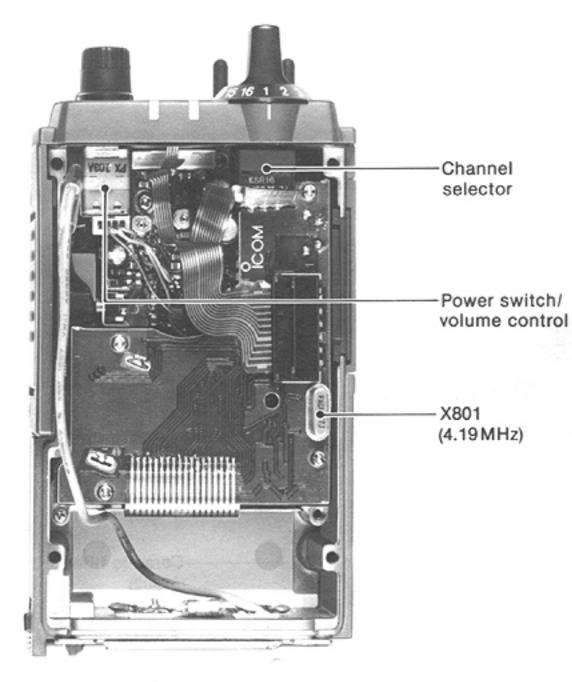
EXTERNAL SPEAKER-MIC JACK

#### • FRONT AND SIDE VIEW



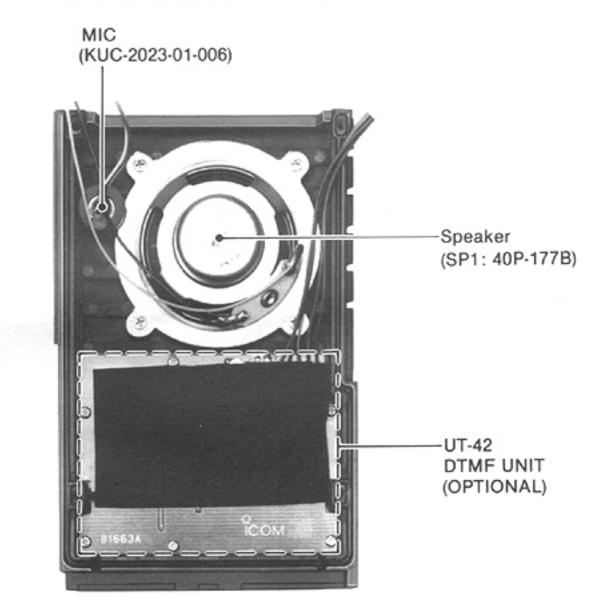
### 2-2 INSIDE VIEWS

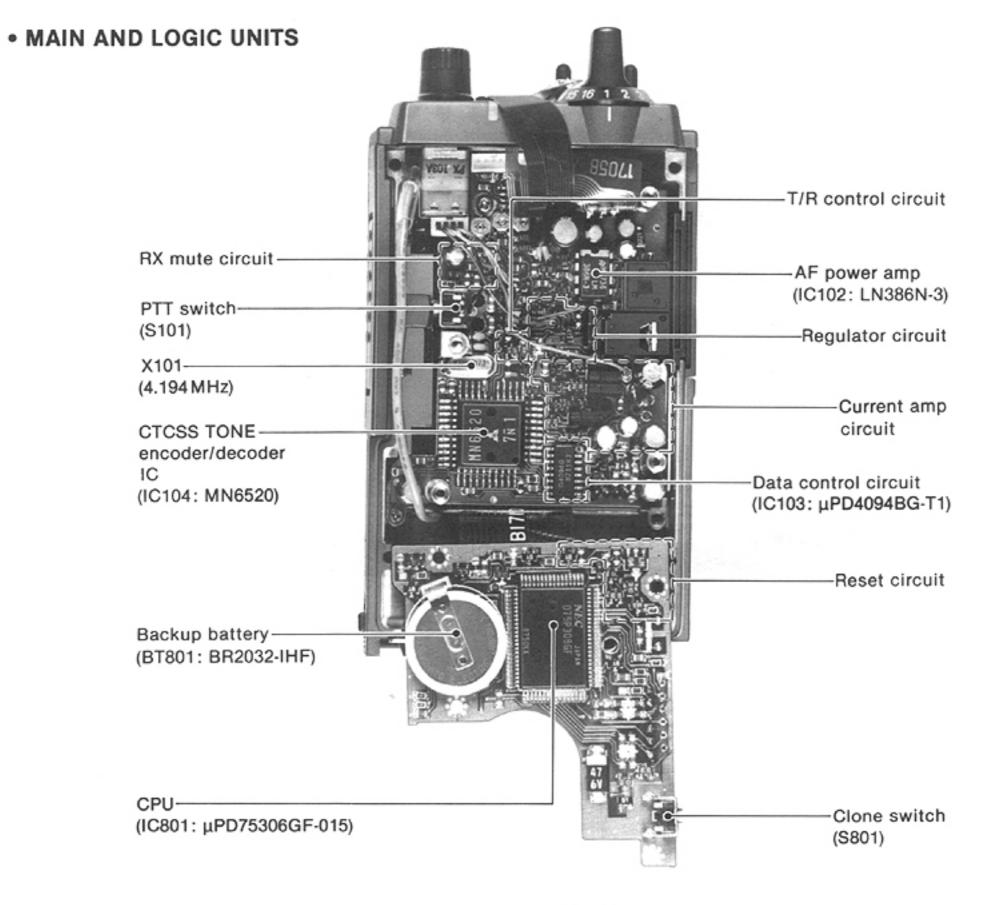
### LOGIC UNIT



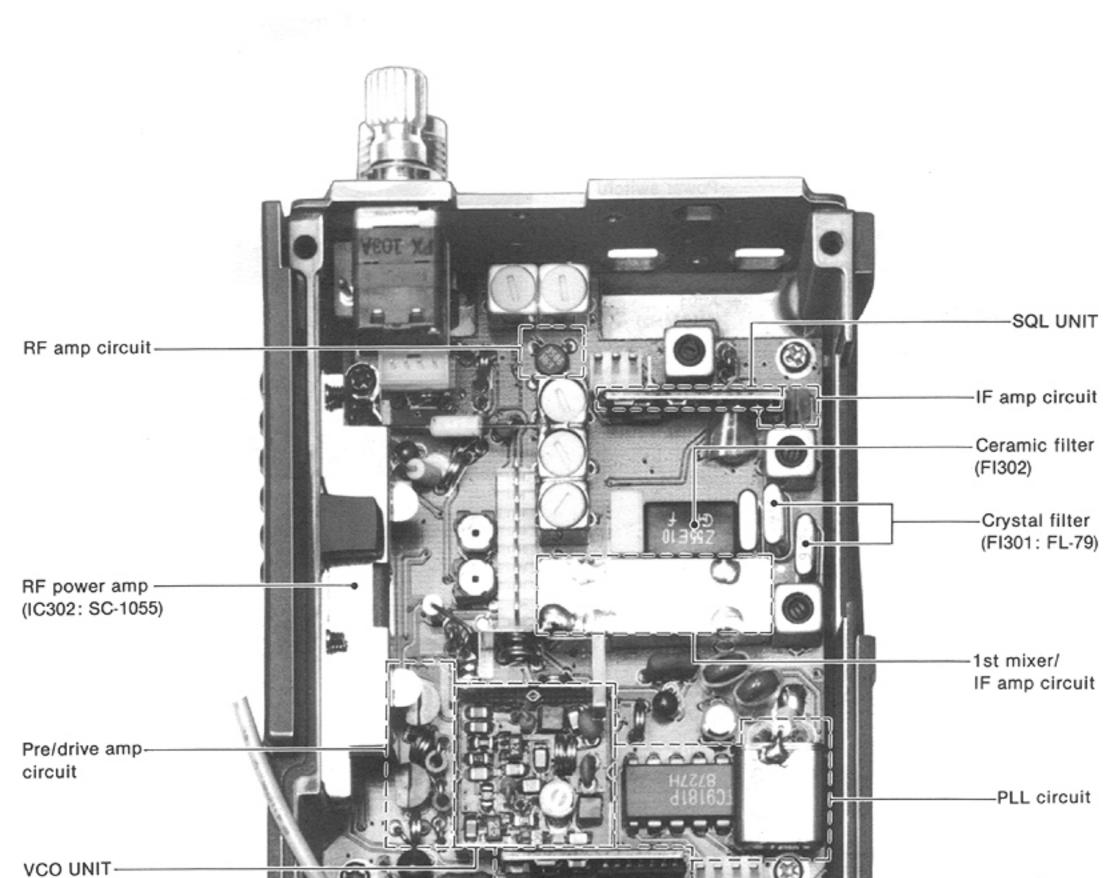
### • FRONT PANEL (Rear side)

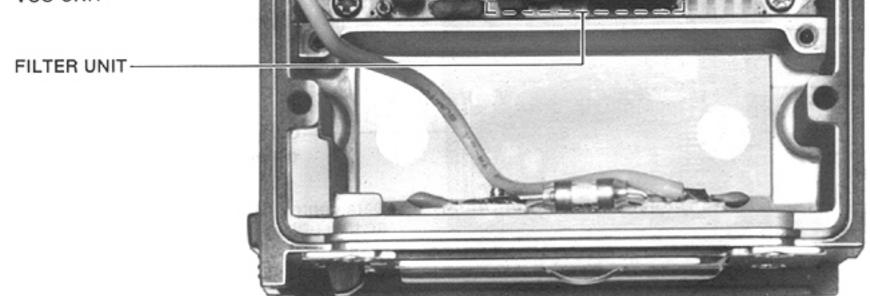
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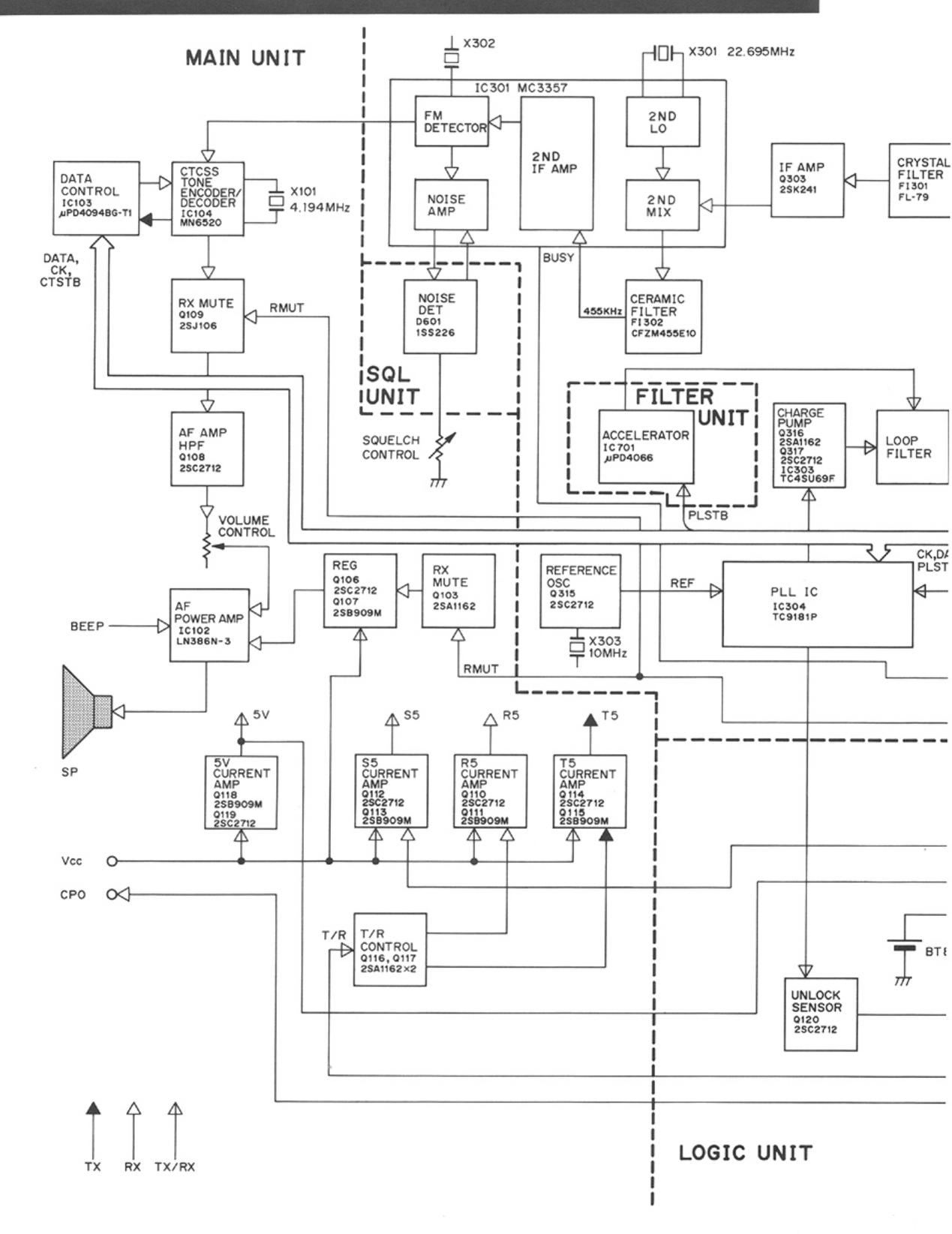




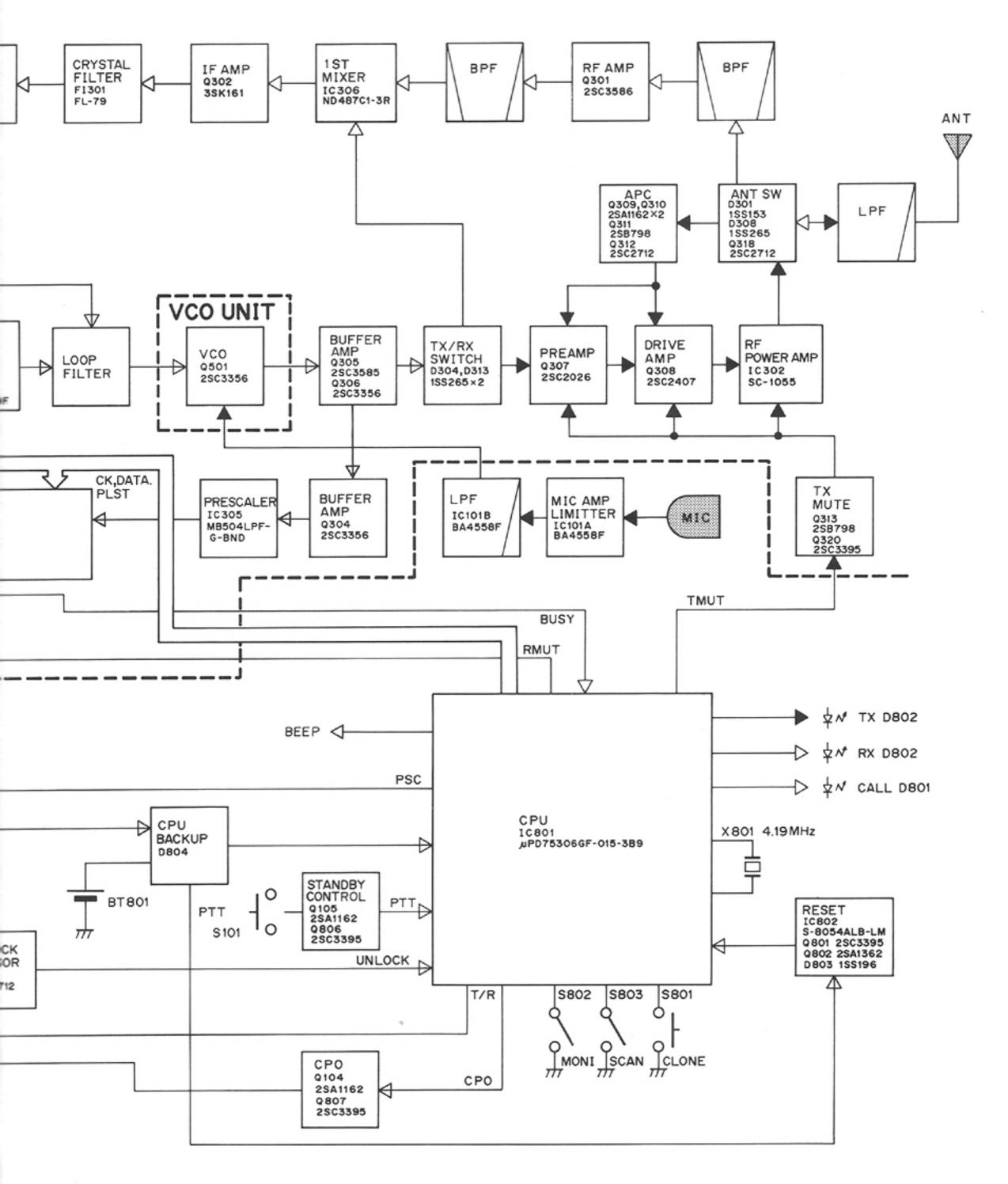




### SECTION 3 BLOCK DIAGRAM







#### SECTION 4 CIRCUIT DESCRIPTION

#### **4-1 RECEIVER CIRCUITS**

#### 4-1-1 ANTENNA SWITCHING CIRCUIT (RF UNIT)

Received signals enter the antenna connector and pass through the  $\pi$ -type two-stage low-pass filter (C379, C381, C383, L319, L320) and the T-network high-pass filter (C375, C378, L318). The signals are applied to the antenna switching circuit (D301, D308, C376, L317) and then to the helical coil band-pass filter (L301). This antenna switching circuit employs a  $\lambda/4$ -type diode switching system.

#### 4-1-2 RF CIRCUIT (RF UNIT)

The filtered RF signals are applied to the RF amplifier (Q301) and reapplied to the bandpass filter (L304) to suppress out-of-band signals.

#### 4-1-3 1st MIXER CIRCUIT (RF UNIT)

This circuit is a double balanced mixer composed of four Schottky barrier diodes (IC306). From the matching transformer (L305), the RF signals are applied to IC306. The product of the 1st LO signal passes through L306 and is applied to IC306. L306 outputs a 23.15 MHz 1st IF signal.

#### 4-1-4 1st IF CIRCUIT (RF UNIT)

After passing through the IF amplifier (Q302) and the matching transformer (L307), the 1st IF signals are applied to the crystal filter (FI301) to suppress outof-band signals. The 1st IF signals are then fed to the 2nd IF circuit via L308.

#### 4-1-5 2nd IF AND DEMODULATOR CIRCUITS (RF UNIT)

The 1st IF signals amplified at IF amplifier (Q303) pass through the matching transformer (L309).

The 1st IF signals from L309 are fed to the 2nd mixer section of IC301 and are mixed with 2nd LO signals to convert the 1st IF signals to 455kHz 2nd IF signals. IC301 contains the 2nd mixer circuit, the 2nd LO circuit and the quadrature circuit. The 2nd LO circuit and X301 generate 22.695MHz 2nd LO signals.

The 2nd IF signals from the 2nd mixer (pin 3 of IC301) pass through the ceramic filter FI302 to suppress unwanted signals. They are then amplified at the limiter amplifier section (pin 5 of IC301) and applied to the quadrature detector section (pin 8 of IC301 and ceramic discriminator X302) to demodulate 2nd IF signals to AF signals.

AF signals output from pin 9 of IC301 are applied to the AF circuit.

#### 4-1-6 AF CIRCUIT (MAIN UNIT)

AF signals from IC301 is fed to pin 29 of IC104. IC104 contains the CTCSS tone encoder/decoder, AF amplifier and two-stage AF filter.

Passing through the AF amplifier section and the two-stage AF filter, the signal is output from pin 18. The -6dB/octave low-pass filter (R155, C153) deemphasizes the signal, which then passes through the muting circuit (Q109). The AF preamplifier (Q108) amplifies the signal to a level sufficient to drive IC102. When the squelch is closed, Q109 activates as the AF switch. Q108 serves as both an AF preamplifier and a high pass filter. The signal passes through the VOLUME CONTROL (R1) and is applied to the AF amplifier (IC102, pin 2). The amplified signal output is 500mW at an 8 $\Omega$  load. IC102 will not be damaged if the battery voltage range is  $7.2 \sim 13.2V$ . The constant voltage circuit (D104, Q106, Q107) provides stable voltage to IC102 pin 6.

#### 4-1-7 SQUELCH CIRCUIT (RF AND LOGIC UNITS)

R604 and R605 are used for temperature compensation. IC301's built-in amplifier (between pins 10 and 11) amplifies noise components 20kHz or more. The output of this amplifier is applied to D601 for detection and rectification. This voltage drives IC301's built-in squelch trigger. After being output from pin 13, the BUSY signal is input to the CPU (IC801) at pin 61. The squelch circuit activates IC801 pin 52. R314 provides hysteresis for high speed squelch switching.

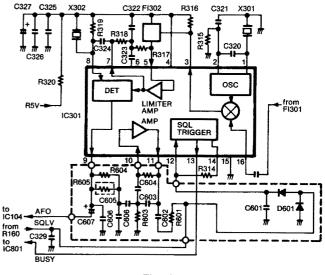


Fig. 1

#### **4-2 TRANSMITTER CIRCUITS**

#### 4-2-1 MICROPHONE AMPLIFIER (MAIN UNIT)

AF signals from a built-in condenser microphone enter IC101A at pin 3 and are preemphasized 6dB/octave through pin 2 by C104 and R102. IC101A functions as the microphone amplifier and the limiter.

The signals pass through the splatter circuit (IC101B, R107, C108, R110, C109, R111, C111) where more than 3kHz is attenuated. IC101 pin 7 then outputs the signals. The signals are applied to D501 of VCO circuit as the modulated signals.

Modulated signals then change the capacitance of D501 to create FM modulation.

#### 4-2-2 DRIVE AMPLIFIER (RF UNIT)

The VCO output is buffer amplified at the buffer amplifier (Q305, Q306).

After passing through the buffer amplifier (Q305, Q306), the diode switch (D313) and preamplifier (Q307), the VCO output is amplified at the drive amplifier (Q308) where 10mW is obtained without adjustment.

The APC circuit controls the voltage supplied to Q307 and Q308, so that stable RF output power is obtained.

#### 4-2-3 RF POWER AMPLIFIER (RF UNIT)

IC302 is a miniature power module which provides stable 5W output within band limits.

The RF signals from the drive amplifier (Q308) are applied to pin 1 of IC302. Power amplified signals are output from pin 5.

#### 4-2-4 APC CIRCUIT (RF UNIT)

The signal then passes through the low-pass filter (C372, C373, L315), producing matched and unmatched voltages which are detected by D306 and D307.

When antenna impedance is matched at  $50\Omega$ , voltage detected at D306 and D307 is at a minimum. However, when antenna impedance is mismatched, the detected voltage is higher than when matched.

The voltage detected at D306 and D307 is fed to the differential amplifier (Q309, Q310). The APC reference voltage is fed to base of Q310.

When the antenna impedance is mismatched, the base voltage of Q309 is higher than the reference voltage. The collector voltage of Q309 decreases, decreasing Q311 and Q312 collector current.

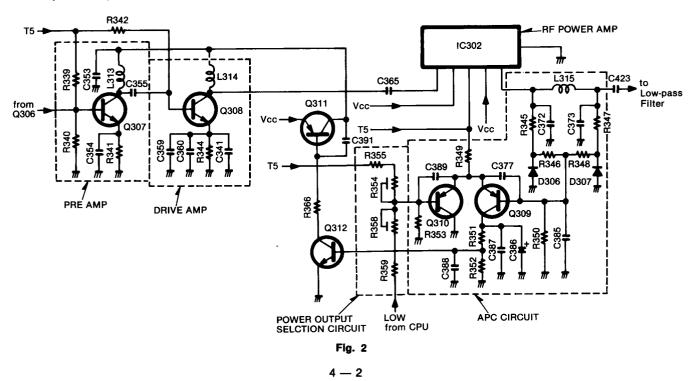
This decreases the output power of the drive amplifier (Q307,Q308) until the base voltage of Q309 equals the base voltage of Q310. Thus, stable RF output power is obtained.

#### 4-2-5 POWER OUTPUT SELECTION CIRCUIT (RF UNIT)

The power selection circuit consists of R353, R354, R355, R358, and R359. This circuit shifts the RF output power by shifting APC reference voltage.

When HIGH output power is programmed, RF output power can be adjusted by R354.

When LOW output power is programmed, a LOW signal is applied from the CPU (IC801). A series combination of R358 and R359 is connected in parallel with R353. RF output power is adjusted by R358.



#### 4-2-6 TX MUTE CIRCUIT (RF UNIT)

"TMUT" signal from the CPU (IC801) turns Q314 OFF. The bias to Q307, Q308 and IC302 is cut off, preventing transmission.

#### 4-2-7 ANTENNA SWITCHING CIRCUIT (RF UNIT)

When transmitting, Q318, D301 and D308 are switched ON. L317 and C302 form a parallel resonant circuit. IC302 output does not enter the receive circuit, but passes through L315, D308 and C375, the low-pass filter (L319, L320, C379, C381, C383) and then on to the antenna.

#### **4-3 PLL CIRCUITS**

#### 4-3-1 GENERAL

The PLL circuit, using a dual modular prescaler (IC304, IC305), is designed such that the desired frequency to be generated directly at the VCO circuit. The dual modular prescaler (IC304, IC305) sets the dividing ratio based on serial data from the CPU (IC801), and compares the phases of the VCO signal and the reference oscillator frequency. It detects the out of step phase and outputs it.

#### **PLL CIRCUIT**

#### 4-3-2 REFERENCE OSCILLATOR CIRCUIT (RF UNIT)

A reference frequency is acquired by Q315, X303 and the divider inside IC304. D310 provides frequency control. The output frequency of this circuit is stable over a large temperature range.

#### 4-3-3 CHARGE PUMP AND LOOP FILTER CIRCUITS (RF UNIT)

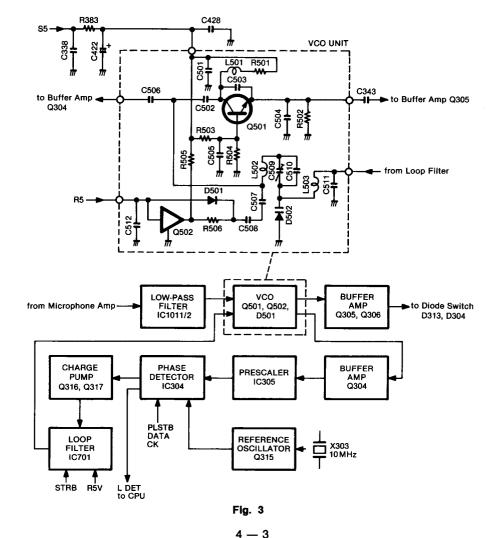
Phase-detected signals from IC304 pins 14 and 15 are converted to DC voltage by the charge pump Q316, Q317 and IC303; and a loop filter consisting of R703  $\sim$  R705 and C702.

VCO oscillating signals are controlled by a varactor diode (D502). DC voltage (PLL lock voltage) is provided by the loop filter.

D701 is an accelerator which ensures rapid PLL lock up time.

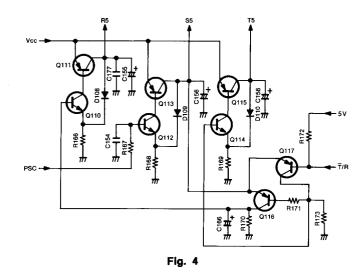
#### 4-3-4 VCO CIRCUIT (VCO UNIT)

Q502 and D501 change the inductive reactance of the Colpitts oscillator (Q501), shifting the receive and transmit frequencies. A variable capacitor (D502) provides frequency control. The buffer amplifier (Q304, Q305, Q306) is unaffected by VCO oscillation.



#### **4-4 VOLTAGE LINES**

LINE	DESCRIPTION
Vcc	NiCd battery used: CM-717.2V, CM-728.4V, CM-7313.2V. Passes through the fuse F1 and the POWER SWITCH and is applied to the power module (IC302), the charge pump (Q316, Q317), AF amplifier (IC102) and the following 5V lines.
+5V	Common 5V voltage with low noise characteris- tics amplified by the constant voltage circuit (Q118, Q119, D111, D112) which receives an input of $6 \sim 16V$ . This circuit employs a comple- mentary amplifier system where it receives high current amplification. Because the heat factor of the combined voltages at Q119 (V <sub>BE</sub> ) and D111 are equal, the output voltage is stable even with regard to temperature changes.
S5	Common 5V controlled by the power save func- tion. Made at Q112, Q113 and D109. When the power save function is turned ON, the CPU (IC801) pin 50 becomes "LOW," turning OFF the 5V from S5, and saving current.
T5	Transmit 5V current amplified at Q115.
R5	Receive 5V controlled by the power save func- tion. Current amplified at Q111.



#### 4-5 T5/R5 SWITCHING CIRCUIT (MAIN UNIT)

When transmitting:

The CPU (IC801) pin 51 becomes "LOW." Q117 is turned ON, and Q116 is turned OFF. Bias voltage is applied to Q114, and Q115 outputs T5V.

#### When receiving:

The CPU (IC801) pin 51 becomes "HIGH," Q117 turned OFF, and Q116 is turned ON. Bias voltage is applied to Q110, and Q111 outputs R5V. Because Q116 supplies voltage through the S5 line, R5 line voltage becomes zero, reducing current consumption when the power save function is ON.

#### 4-6 CTCSS CIRCUIT (MAIN UNIT)

IC104 is a programmable CTCSS encoder/decoder which produces 37 tone frequencies. IC104 pins  $3\sim 8$ (S0 $\sim$ S5) are used to set the tone frequencies for IC103 using serial data from the CPU. When the IC104 transmit/receive switching pin 12 is "LOW," the transceiver transmits; when "HIGH," the transceiver receives.

Cl	rcss	TONE	FREQU	ENCIES:
----	------	------	-------	---------

OUTPUT IC104 INPUT PIN NUMBER						
FREQUENCY [Hz]	3	4	5	6	7	8
67.0	н	L	н	н	н	L
71.9	L	L	Н	н	н	L
74.4	н	н	L	н	н	L
77.0	L	н	L	н	н	L
79.7	н	L	L	н	н	L
82.5	L	L	L	н	н	L
85.4	н	н	н	L	н	L
88.5	L	н	н	L	н	L
91.5	н	L	н	L	н	L
94.8	н	L	L	н	н	н
100.0	L	L	L	н	н	н
103.5	н	н	н	L	н	н
107.2	L	н	н	L	н	н
110.9	н	L	н	L	н	н
114.8	L	L	н	L	н	н
118.8	н	н	L	L	н	н
123.0	L	н	L	L	Н	H.
127.3	н	L	L	L	н	н
131.8	L	L	L	L	н	н
136.5	н	н	н	н	L	н
141.3	L	н	н	н	L	н
146.2	н	L	н	Н	L	н
151.4	L	L	н	н	L	н
156.7	н	н	L	н	L	Н
162.2	L	н	L	Н	L	Н
167.9	н	L	L	Н	L	Н
173.8	L	L	L	Н	L	н
179.9	н	н	н	L	L	н
186.2	L	Н	Н	L	L	Н
192.8	н	L	Н	L	L	Н
203.5	L	L	н	Ĺ	L	н
210.7	н	н	L	L	L	Н
218.1	L	Н	L	L	L	н
225.7	н	L	L	L	L	н
233.6	L	L	L	L	L	Н
241.8	н	н	н	Н	Н	L
250.3	L	н	н	н	Н	L

### 4-7 CPU (IC801) PORTS

#### INPUT PORT

PIN	PORT	NAME	DESCRIPTION
38	P00	INT4	Interrupt input HIGH: Normal operation LOW: Puts the CPU on standby.
41	P03	HIGH/LOW	<ul> <li>HIGH: Low RF output has been selected.</li> <li>LOW: High RF output has been selected.</li> <li>The RF output remains high when low output is written into the memory.</li> </ul>
42	P10	PTT	LOW: PTT SWITCH has been pushed.
43	P11	CLONE	LOW: CLONING SWITCH has been pushed. Pressing the CLONING SWITCH when the power is ON activates the cloning function.
44	P12	MONI	LOW: MONITOR SWITCH is pushed. The CPU turns OFF the CTCSS tone decoder when the port is "LOW."
45	P13	SCAN CONTROL	Starts a scan when "LOW."
	P40~P43		Matrix input.
60	P60	DET	Equalizes tones when "HIGH."
61	P61	BUSY	Opens the squelch when "HIGH."
62	P62	UNLOCK	Unlocks the PLL when "LOW."

#### OUTPUT PORT

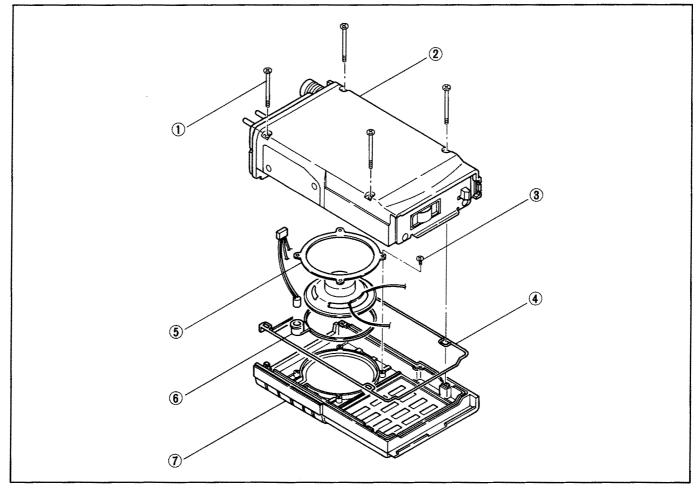
PIN	PORT	NAME	DESCRIPTION
34	P50	KS4	Matrix signal output. (Matrix is used for CH selection.)
35	P51	KS5	Matrix signal output.
36	P52	LOWO	Power control signal output. Outputs "LOW" when the HIGH/LOW power switch is set to low power output.
37	P53	TMUT	Transmit mute output.
39	P01	СК	Serial data output.
40	P02	DATA	Serial data output.
46	P20	BEEP	Outputs a 1kHz pulse when a beep is emitted over the speaker.
47	P21	PLSTB	Strobe signal output for the PLL.
48	P22	CTSTB	Strobe signal output for the CTCSS tone encoder/decoder
49	P23	TONEC	2-tone control signal output. Becomes "LOW" when DPL of SINGLE tone is selected.
50	P30	PSC	Power save control output. Becomes "LOW" when the power save function is activated.
51	P31	Ŧ/R	Transmit/Receive switching output. Becomes "LOW" with input when transmitting.
52	P32	RMUT	Receiver mute output. Becomes "HIGH" when receiver audio output is muted.
53	P33	CALLO	Busy signal output. Outputs a signal synchronized with the BUSY input. Directly drives the TRANSMIT/BUSY INDICATOR.
63	P63	CPO	CLONE DATA output.
	P70~P73		Matrix signal output pins.

### SECTION 5 MECHANICAL PARTS AND DISASSEMBLY

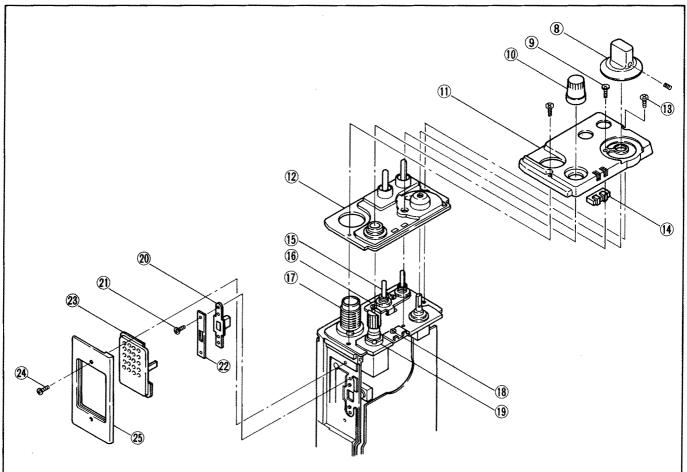
LABELLED NUMBER	DESCRIPTION	ORDERING NUMBER	QTY.	
0	PH B0 2×31.5 ZK	8810004000	4	
2	Rear panel	8010007230	1	
3	PH B0 2×4	8810000980	4	
٩	Casing seal	8010007240	1	
5	Speaker plate	8930012480	1	
6	Speaker seal	8930012630	1	
1	Front panel (A)	8210003220	1	
8	Knob (channel) N-132 (includes HLH M3×3)	8610004300 (8810003520)	1	
9	No. 0-1 PH M2×7 ZK	8810005100	1	
0	Knob (Power/Volume) N-133	8610004310	1	
 	Top panel	8210003180	1	
 	Top panel seal	8930012560	1	
 	PH M2×6 ZK	8810004860	2	
<u> </u>	Lens	8930012600	1	
 (j)	No. 0-1 PH M2×2.5	8810004870	2	
 (6)	Top plate	8310012090	<u> </u>	
- Ŭ	Antenna connector TNC-R107 (includes nut)	6510007250	1	
10	No. 0-1 PH M2×2.5	8810004870	1	
19	VR nut (E)	8830000550	1	
20	Switch seal	8310012280	1	
<u></u>	PH M2×6	881000030	2	
20	Switch plate	8930012500	1	
23	PTT button	8930012570	1	
29	No. 0-1 PH M2×5 ZK	8810000530	2	
8	PTT holder	8930012590	1	
20	PH M2×3	8810004210	4	
Ð	PH M2×3 ZK	8810005090	2	
28	Side plate	8930012580	1	
29	Jack cover seal	8930012620	1	
<u></u>	Standoff (AR)	8930012510	3	
<u></u>	No. 0-1 PH M2×2.5	8810004870	3	
80	PH M2×3	8810004210	4	
3	PH M2×6	8810000030	1	
<u>.</u>	Module mounting plate	8930012490	1	
<u></u>	Screw lug M2	8860000010	2	
30	Spring (K)	8930012640	1	
<u>)</u>	Release button	8930012610	1	
89	BH M2×6 Ni	8810002580	2	
<u></u>	Sliding guide (A)	8010007180	1	
40	FH M2×4 Ni	8810002310	4	
	Connection spring	8930005980	1	
<u></u>	Contact holder	8930011880	1	

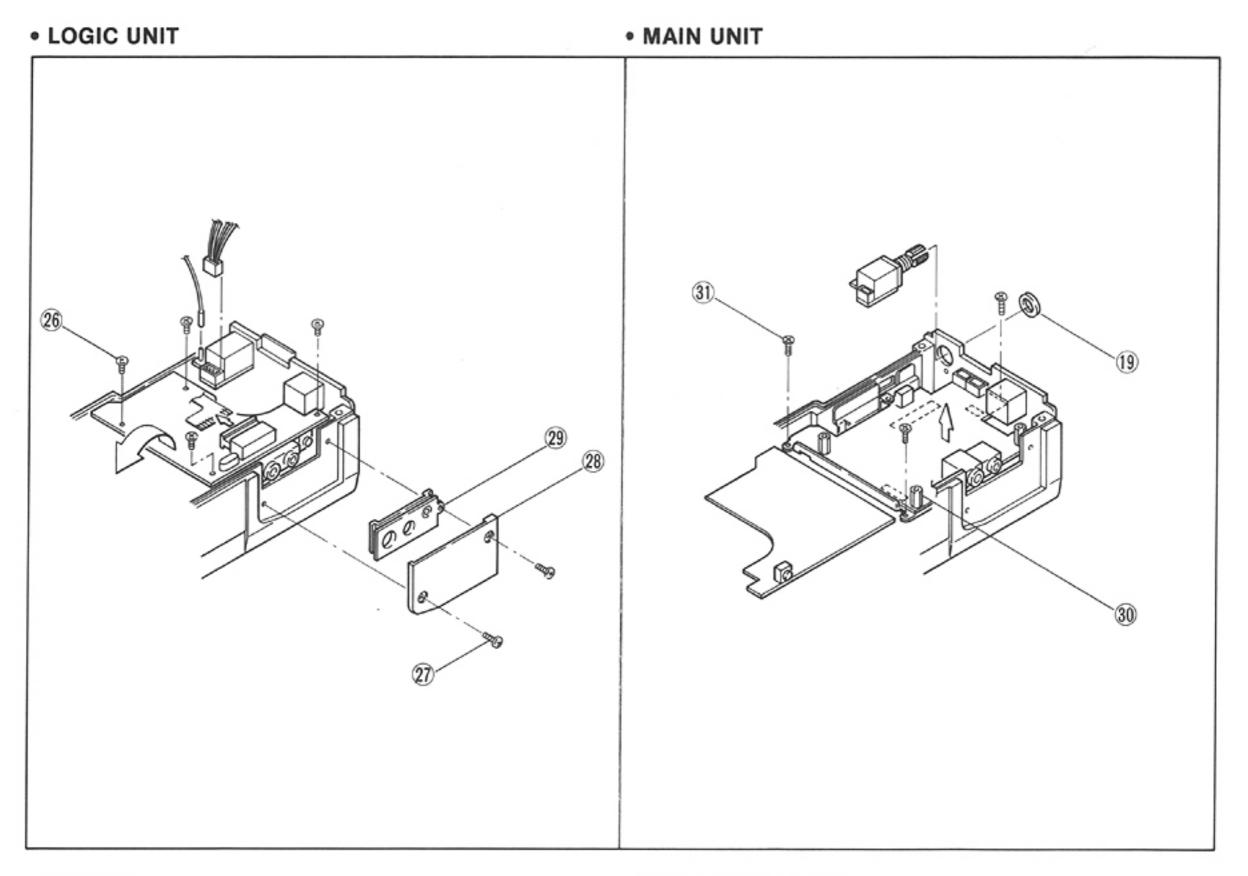
Screw typeScrew: M2×6, etc.Self-tapping screw: B0 2×4, etc.Precision type screw: No. 0-1Screw's head stylePH: Pan headBH: Button headFH: Flat headHLH: Headless hex head

• CASE AND FRONT PANELS



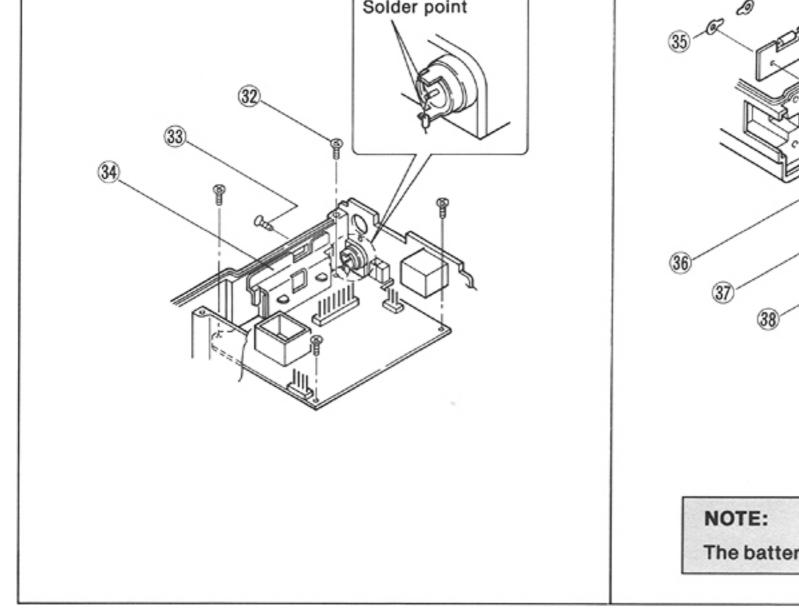
• TOP PANEL

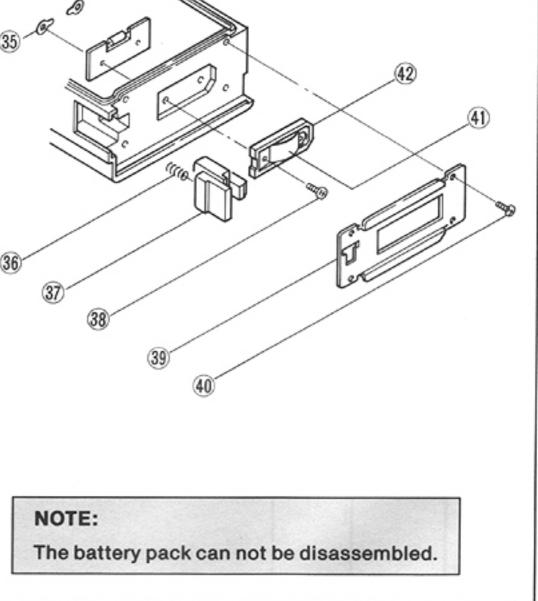




### • RF UNIT

### • CONTACT HOLDER



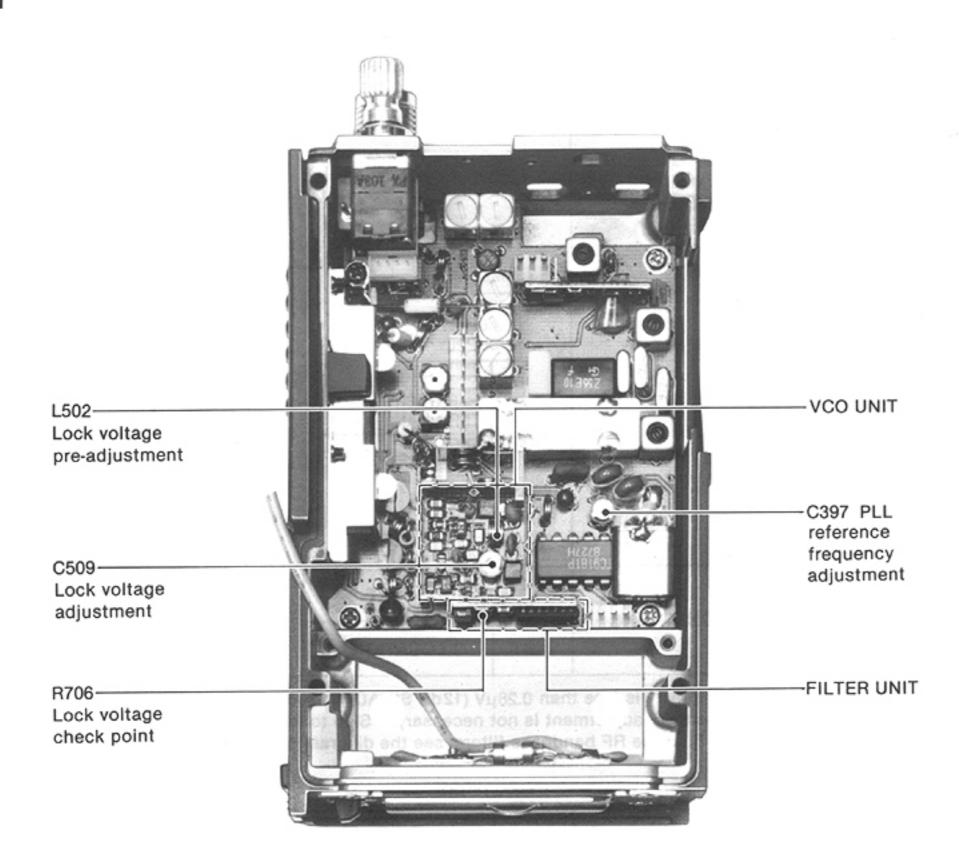


### SECTION 6 ADJUSTMENT PROCEDURES

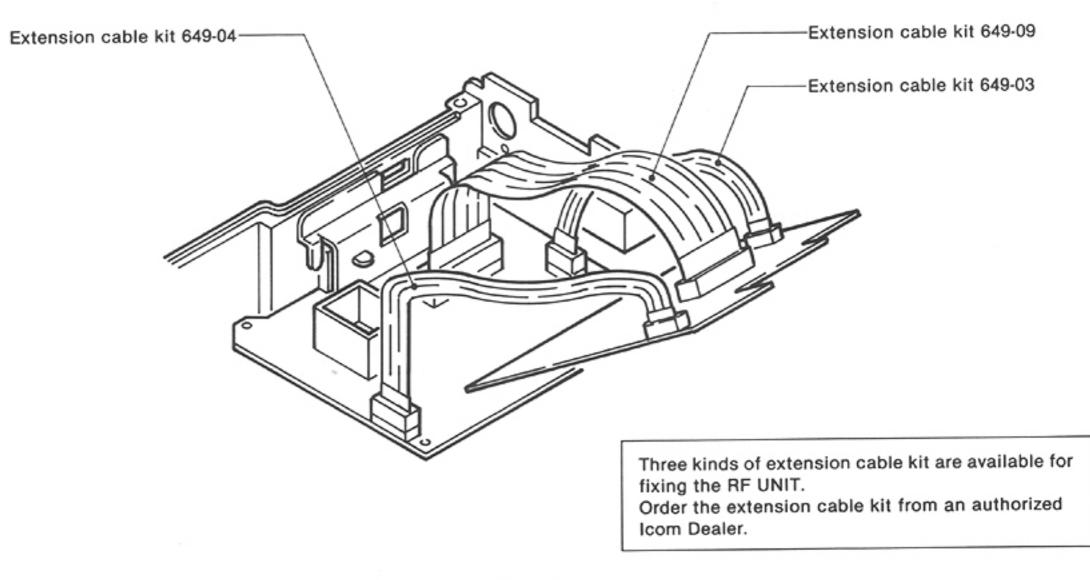
### 6-1 PLL ADJUSTMENT

TEST INSTRUMENTS REQUIRED         (1) AC POWER SUPPLY       • Output voltage       : 13.2V DC         • Output voltage       : 13.2V DC         • Current capacity       : 3A or more         (2) FREQUENCY COUNTER         • Frequency range       : 0.1~480 MHz         • Frequency accuracy       : ± 1 ppm or better         • Sensitivity       : 100mV or better         (3) DC VOLTMETER       • Input impedance         • Input impedance       : 50 kΩ/DC or better			MEASUREMENT CONNECTION LOCATION					
				AC POWER SUPPLY to BATTERY TERMINAL Loose couple to ante TRANSCEIVER to R706				
			N	IEASUREMENT			STMENT OINT	
ADJUSTMENT		ADJUSTMENT CONDITIONS	UNIT	LOCATION	- VALUE	UNIT	ADJUST	
PLL REFERENCE FREQUENCY	1	<ul> <li>Select any channel.</li> <li>Transmitting</li> <li>Connect an antenna.</li> </ul>	Top panel	Loose couple the frequency counter to the antenna.	Same frequency as the programmed one. To check the programmed frequency, use the EX-704.	RF	C397	
	1							
LOCK VOLTAGE		NOTE: Lock voltage affects the C/I frequency with the EX-704.	N ratio. I	f you adjust the lock	voltage, set the			
	1		FILTER		voltage, set the	vco	C509	
	1	frequency with the EX-704. • Operating frequency: 450.0000 MHz	1	Connect the DC	_	vco	C509 Verify	
VOLTAGE LOCK VOLTAGE PRE-		frequency with the EX-704. • Operating frequency: 450.0000 MHz • Receiving	FILTER	Connect the DC voltmeter to R706.	1.2V 1.2~2.8V	vco		
VOLTAGE		frequency with the EX-704. • Operating frequency: 450.0000 MHz • Receiving • Transmitting	FILTER	Connect the DC voltmeter to R706.	1.2V 1.2~2.8V	vco		
VOLTAGE LOCK VOLTAGE PRE- ADJUST-	2	frequency with the EX-704. • Operating frequency: 450.0000 MHz • Receiving • Transmitting NOTE: When replacing L502, the for • Operating frequency: 450.0000 MHz	FILTER	Connect the DC voltmeter to R706. e-adjustment is neces	1.2V 1.2~2.8V ssary.		Verify	

### **RF UNIT**

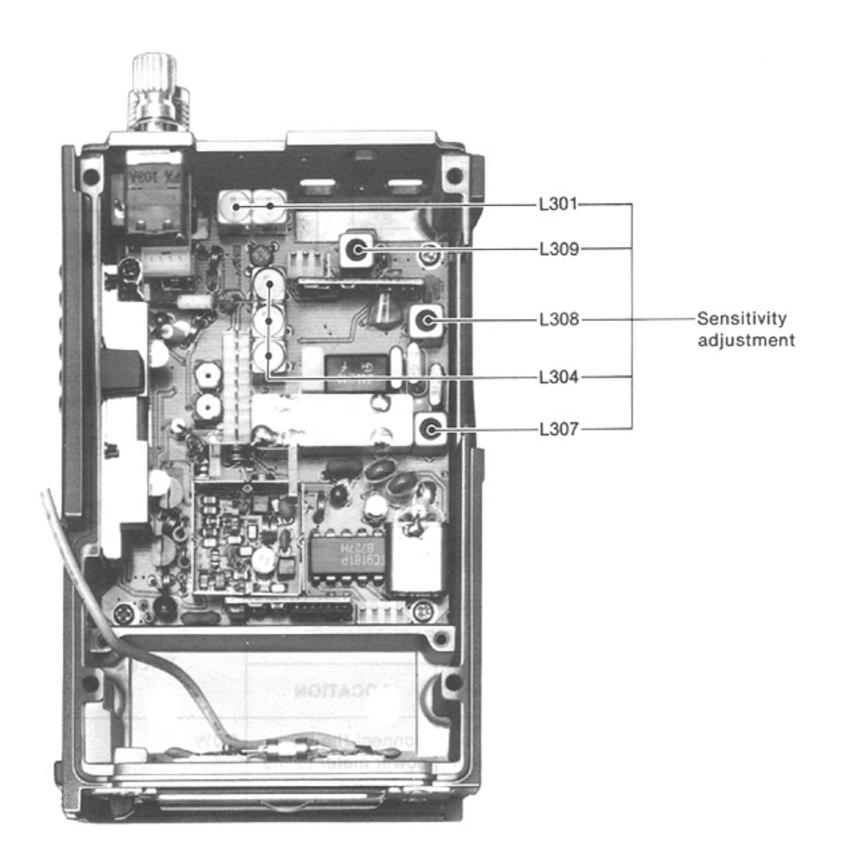


#### **RF AND MAIN UNITS SEPARATION**

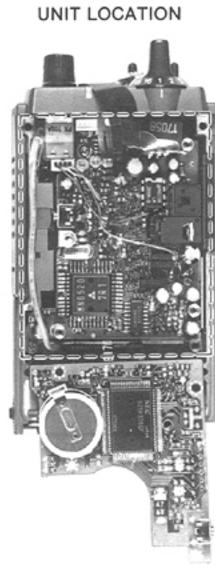


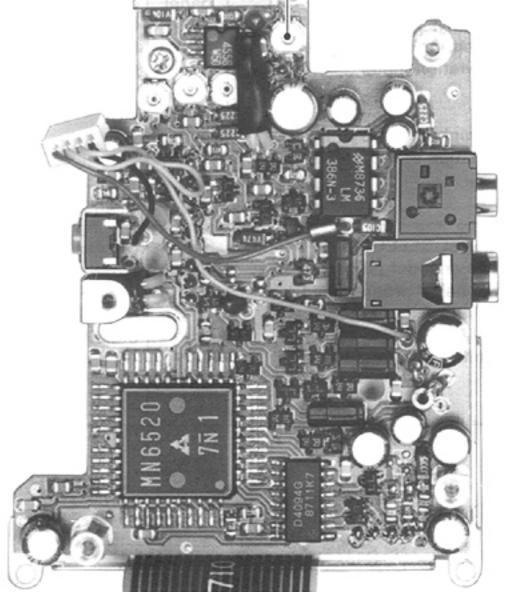
#### 6-2 RECEIVER ADJUSTMENT

Т	TEST INSTRUMENTS REQUIRED			MEASUREMENT CONNECTION LOCATION				
<ul> <li>(1) AC POWER SUPPLY <ul> <li>Output voltage</li> <li>Current capacity</li> <li>3A or more</li> </ul> </li> <li>(2) STANDARD SIGNAL GENERATOR (SSG) <ul> <li>Frequency range</li> <li>0.1~480 MHz</li> <li>Output level</li> <li>-127~-17 dBm</li> <li>(0.1µV~32mV)</li> </ul> </li> <li>(3) DISTORTION METER <ul> <li>Frequency range</li> <li>1 kHz±10 Hz</li> <li>Measuring range</li> <li>1~100%</li> </ul> </li> <li>(4) EXTERNAL SPEAKER <ul> <li>Impedance</li> <li>8Ω</li> </ul> </li> </ul>				DISTORTION METER AC POWER SUPPLY to BATTERY TERMINAL		STANDA SIGNAL GENERA o ANTENN CONNECTO		
ADJUSTME	NT	ADJUSTMENT CONDITIONS	N	IEASUREMENT	VALUE		STMENT DINT	
Abtoorme			UNIT	LOCATION		UNIT	ADJUST	
SENSITIVITY	1	<ul> <li>NOTE: When the sensitivity is less following sensitivity adjustm below. To adjust the RF ba</li> <li>Operating frequency: Center of the frequency edge.</li> <li>Receiving</li> <li>Apply an RF signal to the ANTENNA CONNECTOR. Level: -116dBm (0.35µV) Mod.: 1kHz Dev.: ±3.5kHz</li> <li>MONITOR SWITCH: ON</li> </ul>	ent is no	t necessary. Skip to	squeich adjustment	RF	L301 L304 L307 L308 L309	
SQUELCH	SQUELCH NOTE: Before squeich adjustment, be sure that the sensitivity on every channel are less than 0.28µV (12dB SINAD).							
	1	<ul> <li>Apply an RF signal to ANTENNA CONNECTOR: Level: - 120dBm (0.22µV) Mod.: 1 kHz Dev. : ±3.5 kHz</li> <li>Turn R160 max. counterclockwise.</li> </ul>	Front panel	Speaker	Squelch threshold point	MAIN	R160	



### MAIN UNIT



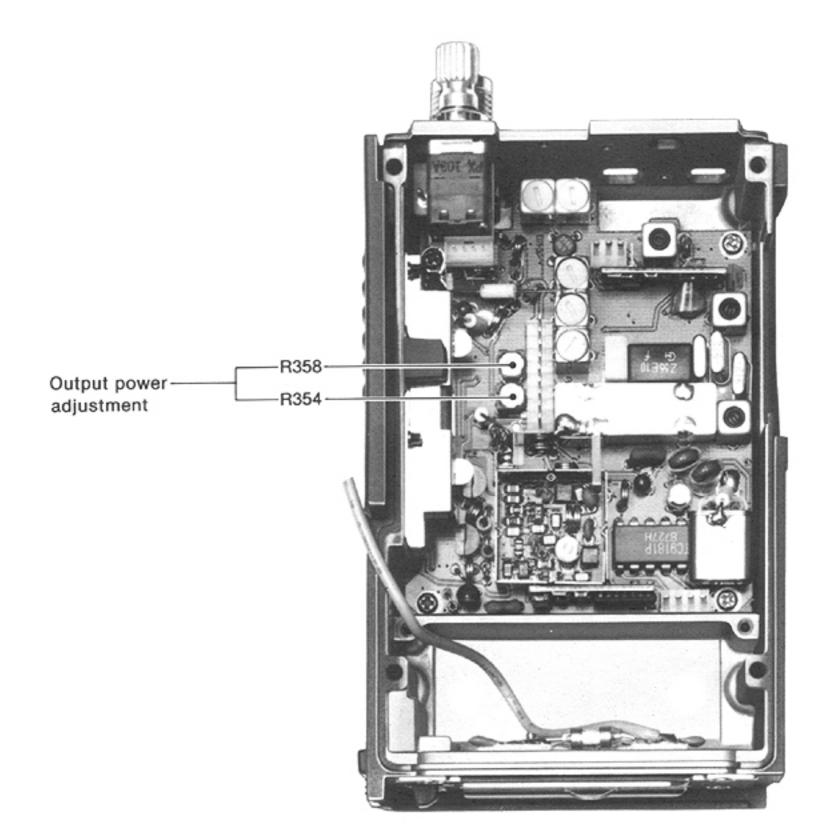


-R160 Squeich adjustment

#### **6-3 TRANSMITTER ADJUSTMENT**

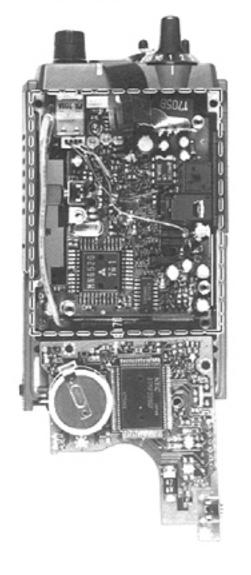
TEST INSTRUMENTS REQUIRED				MEASUREMENT CONNECTION LOCATION			
<ul> <li>(1) AC POWER SUPPLY <ul> <li>Output voltage : 13.2V DC</li> <li>Current capacity : 3A or more</li> </ul> </li> <li>(2) RF POWER METER (TERMINATED TYPE) <ul> <li>Measuring range : 1~10W</li> <li>Frequency range : 440~480 MHz</li> <li>Impedance : 50Ω</li> <li>SWR : Less than 1.2:1</li> </ul> </li> <li>(3) AF GENERATOR (AG) <ul> <li>Frequency range : 200~2000 Hz</li> <li>Output level : 0~200 mV</li> </ul> </li> <li>(4) AC MILLI-VOLTMETER <ul> <li>Measuring range : 2~200 mV</li> </ul> </li> <li>(5) FM DEVIATION METER <ul> <li>Frequency minimum : 480 MHz</li> <li>Measuring range : 0~±5 kHz</li> </ul> </li> </ul>			MILLI- LTMETER	MIC JACK to ANTENNA CONNECTOR TRANSCEIVER	ATTEN more th	UATOR: han 40dB	
ADJUSTMENT		ADJUSTMENT CONDITIONS	MEASUREMENT			ADJUSTMENT POINT	
			UNIT	LOCATION	VALUE	UNIT	ADJUST
OUTPUT POWER		• Select any channel. • Transmitting	Top panel	Connect the RF power meter to the ANTENNA CONNECTOR.	5.0W	RF	R354
	2	CHANNEL SELECTOR: Low power channel, if programmed.			1.5W		R358
DEVIATION	4	<ul> <li>Select any channel</li> <li>Apply an AF signal to the EXT. MIC JACK: 1kHz/170mV</li> <li>Transmitting</li> <li>FM deviation meter HPF : OFF LPF : 20kHz Deemphasis : OFF Deviation sense: P-P/2</li> </ul>	Top panel	Connect the FM deviation meter to the ANTENNA CONNECTOR via the attenuator.	±4.2kHz	MAIN	R116
CTCSS DEVIATION	1	<ul> <li>CHANNEL SELECTOR: Tone encoder programmed channel, if programmed.</li> <li>Apply no AF signal to the EXT. MIC JACK.</li> <li>Tranmitting</li> </ul>	Top panel	Connect the FM deviation meter to the ANTENNA CONNECTOR via the attenuator.	±0.75kHz	MAIN	R118

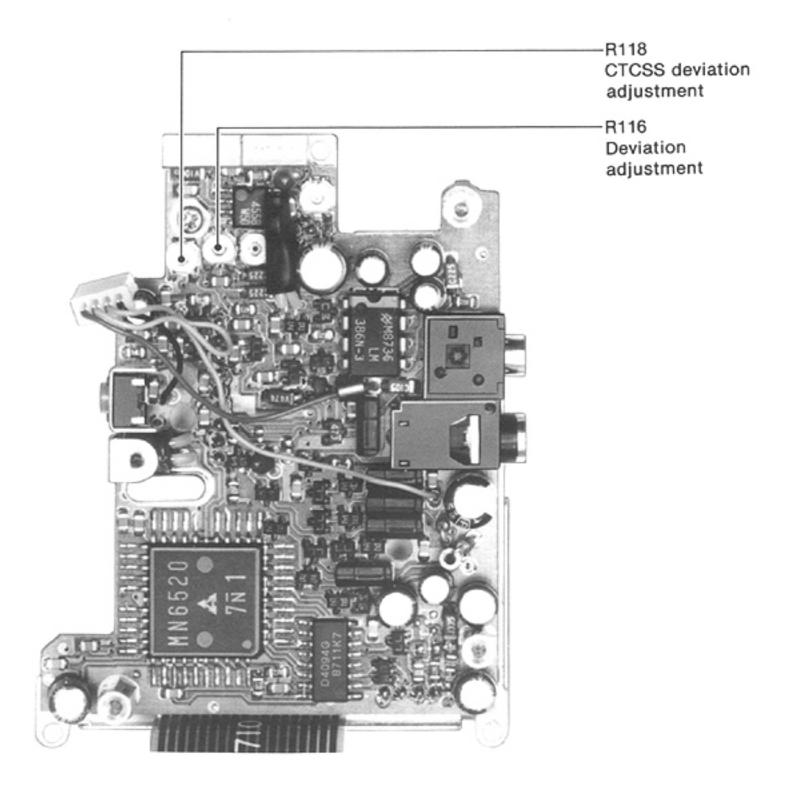
**RF UNIT** 



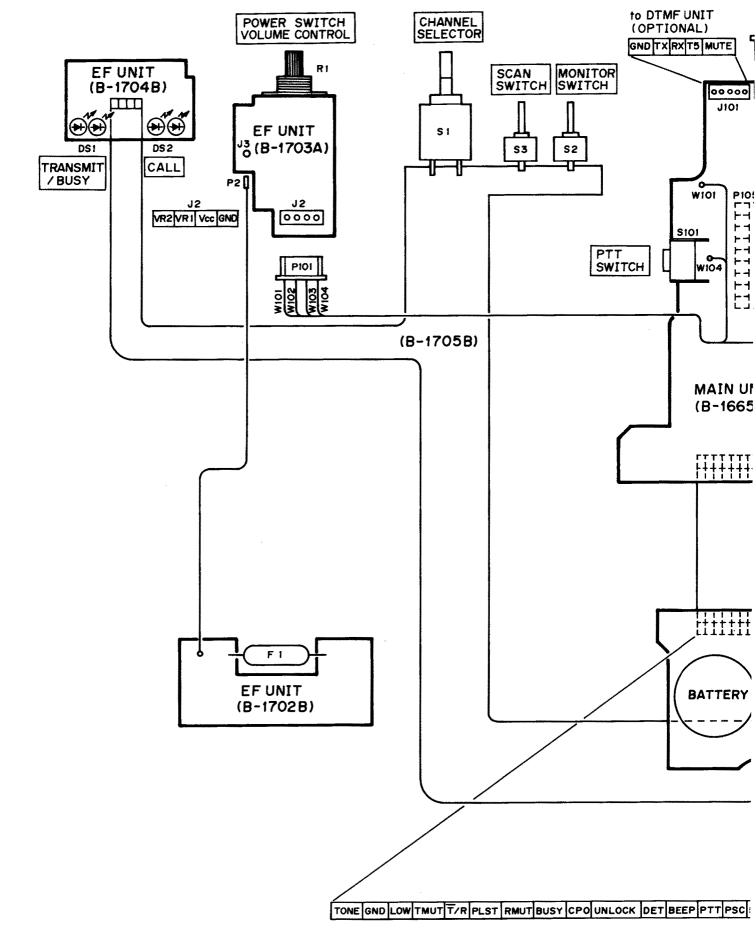
MAIN UNIT

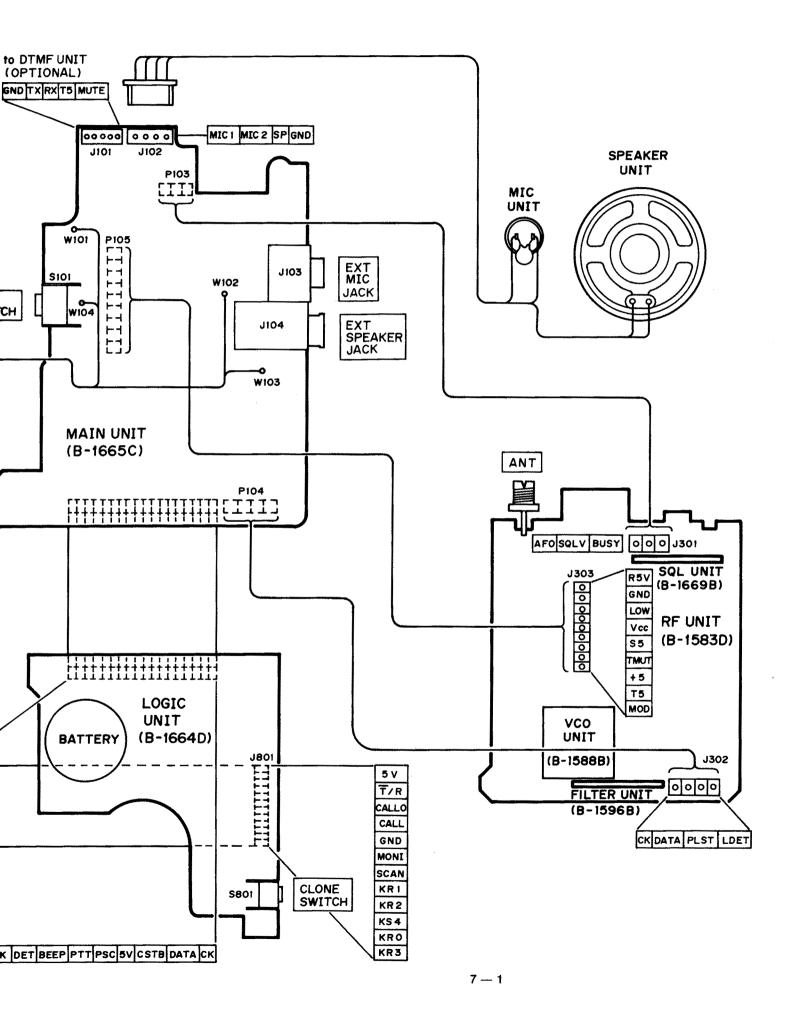
UNIT LOCATION





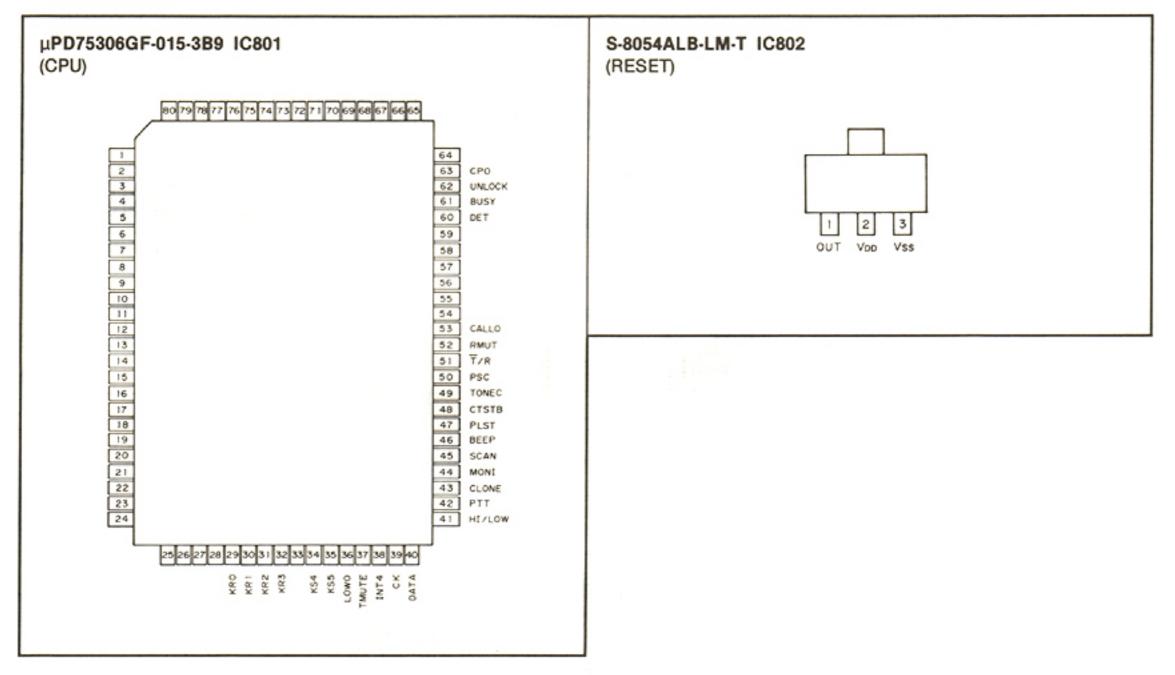
#### **7-1 INTERCONNECTION**





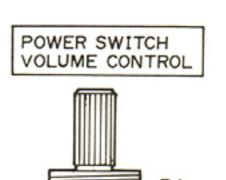
### 7-2 LOGIC AND EF UNITS

LOGIC UNIT

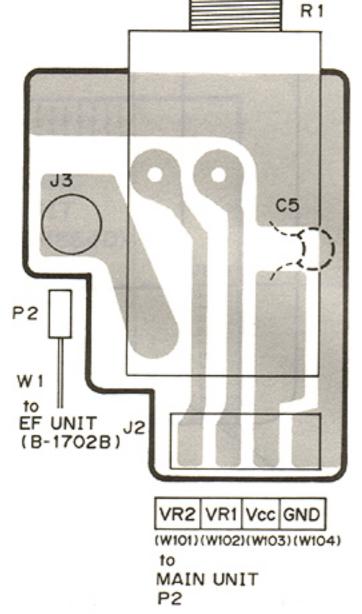


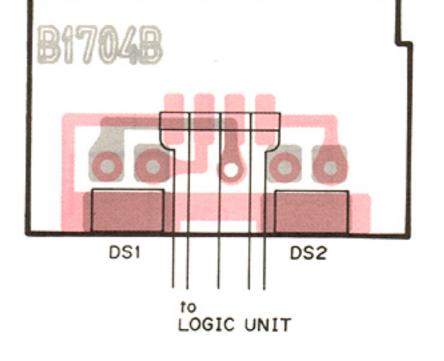
• EF UNIT

VOL



LED



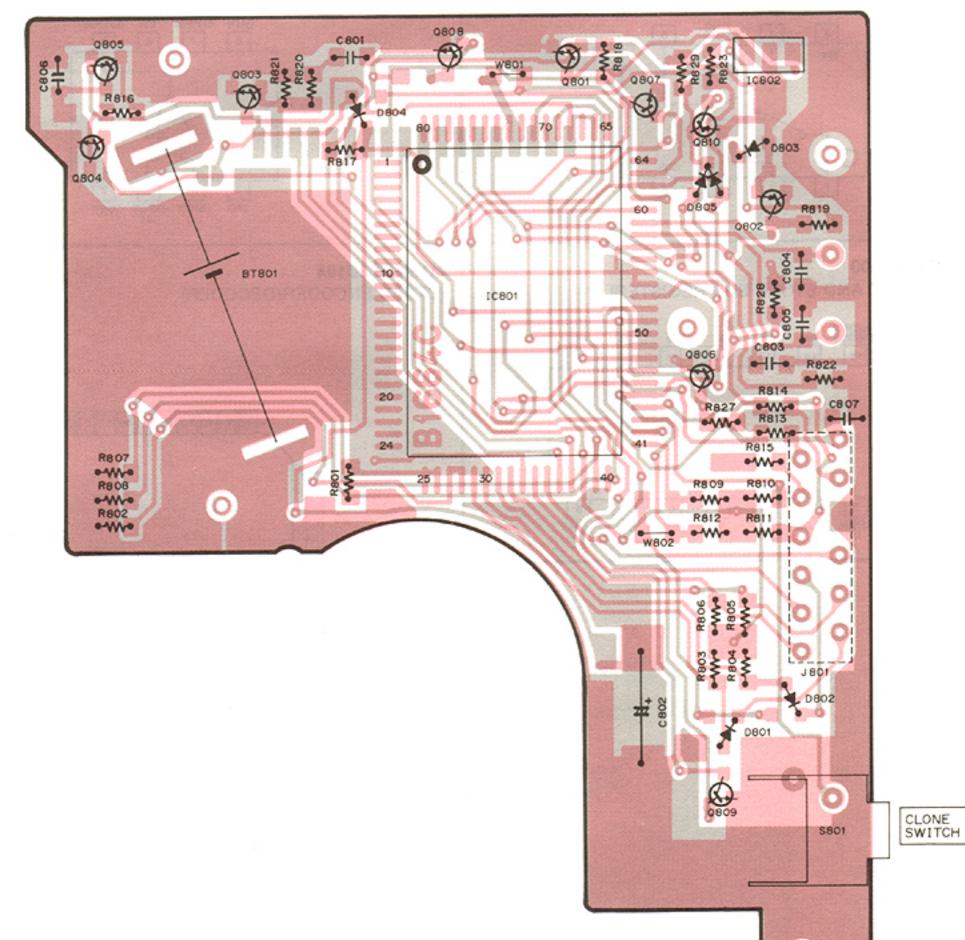


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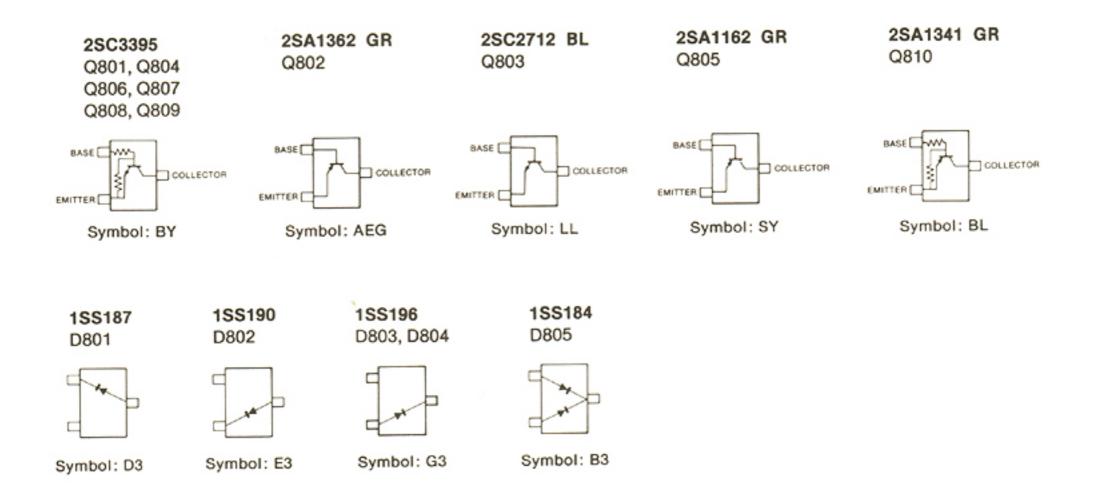


### LOGIC UNIT

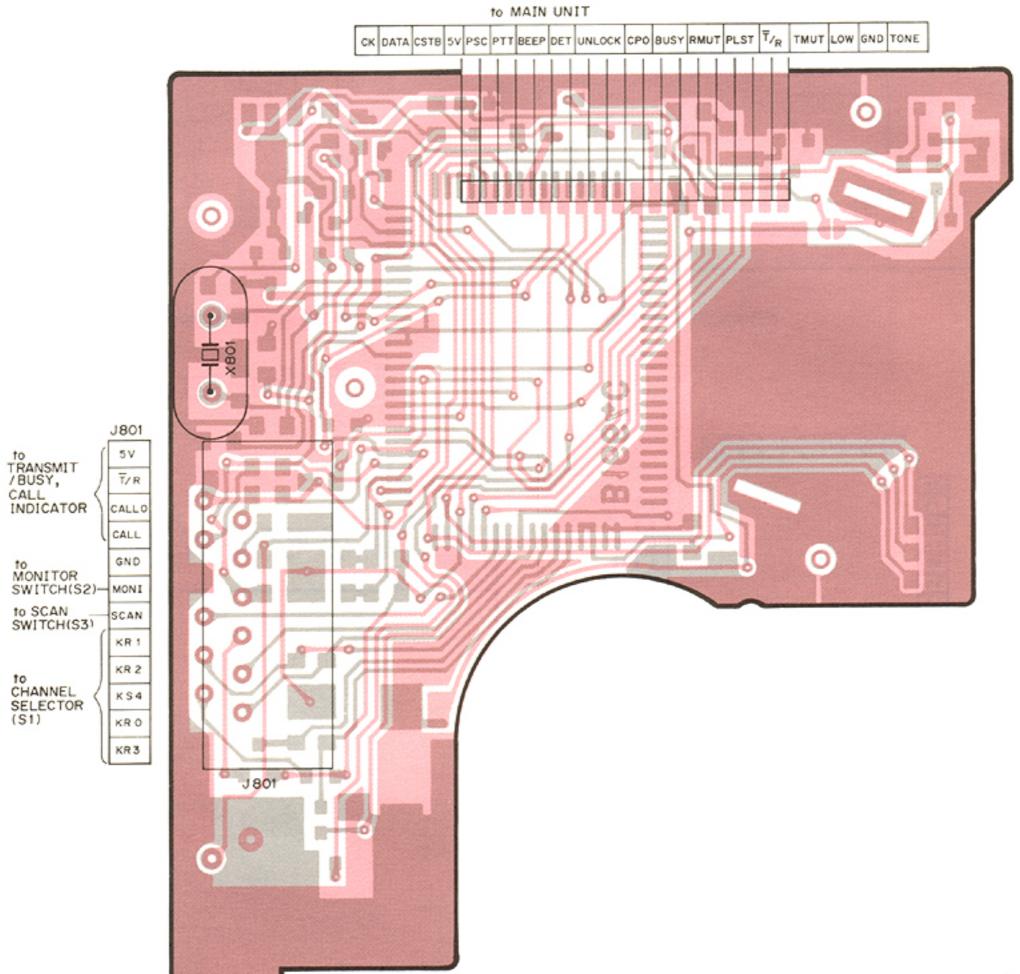
COMPONENTS SIDE







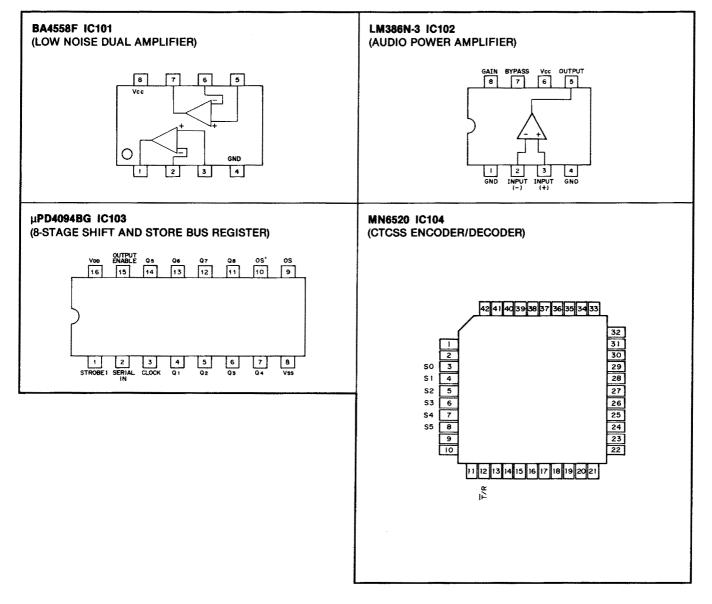
. . .



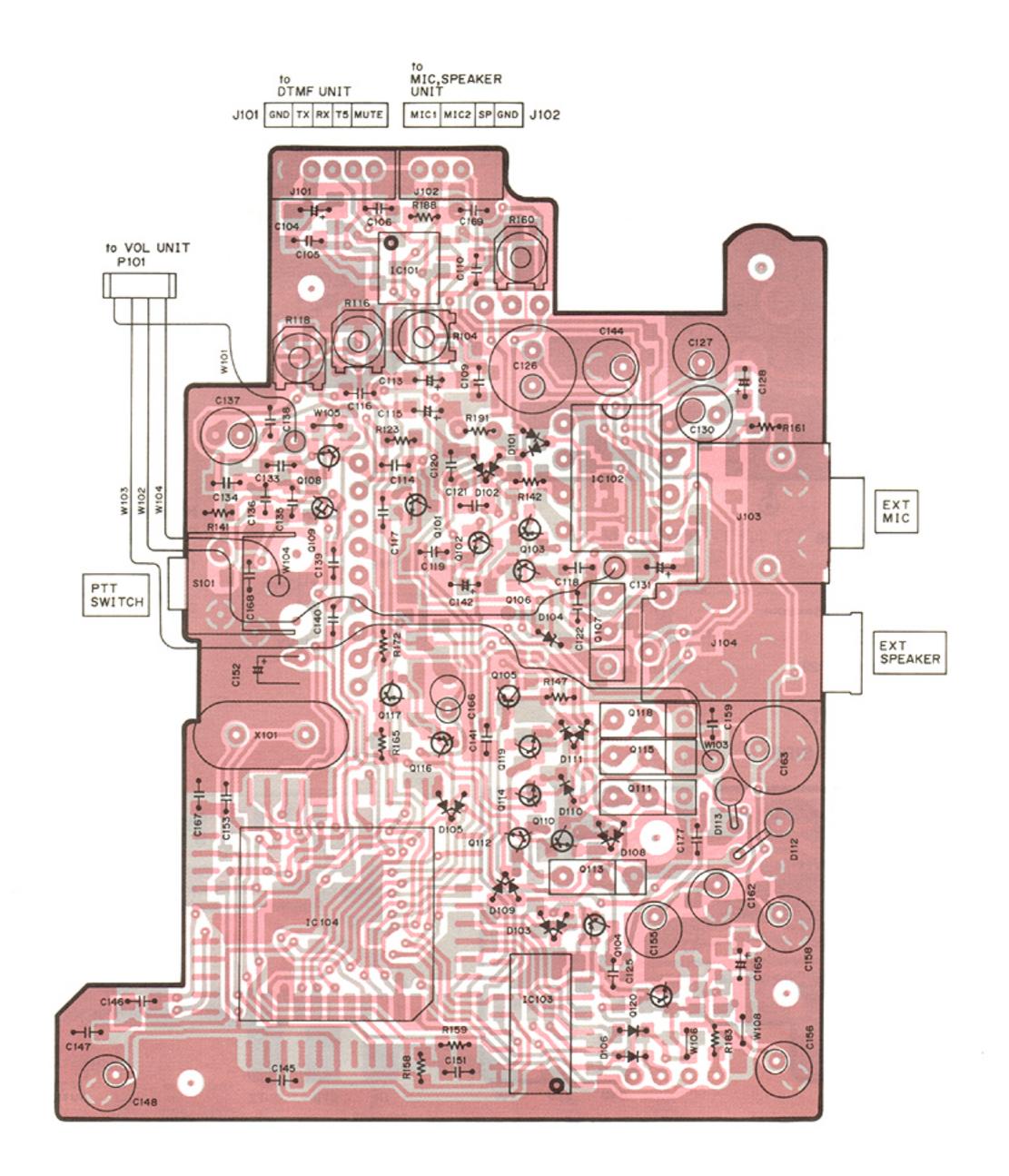


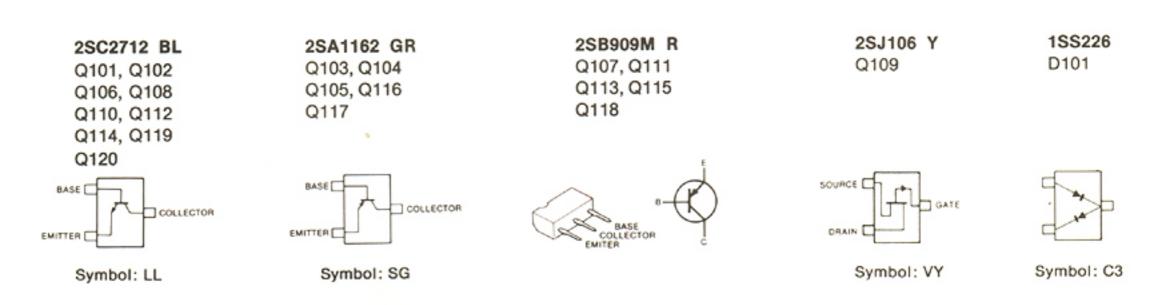
7 — 3

#### 7-3 MAIN UNIT

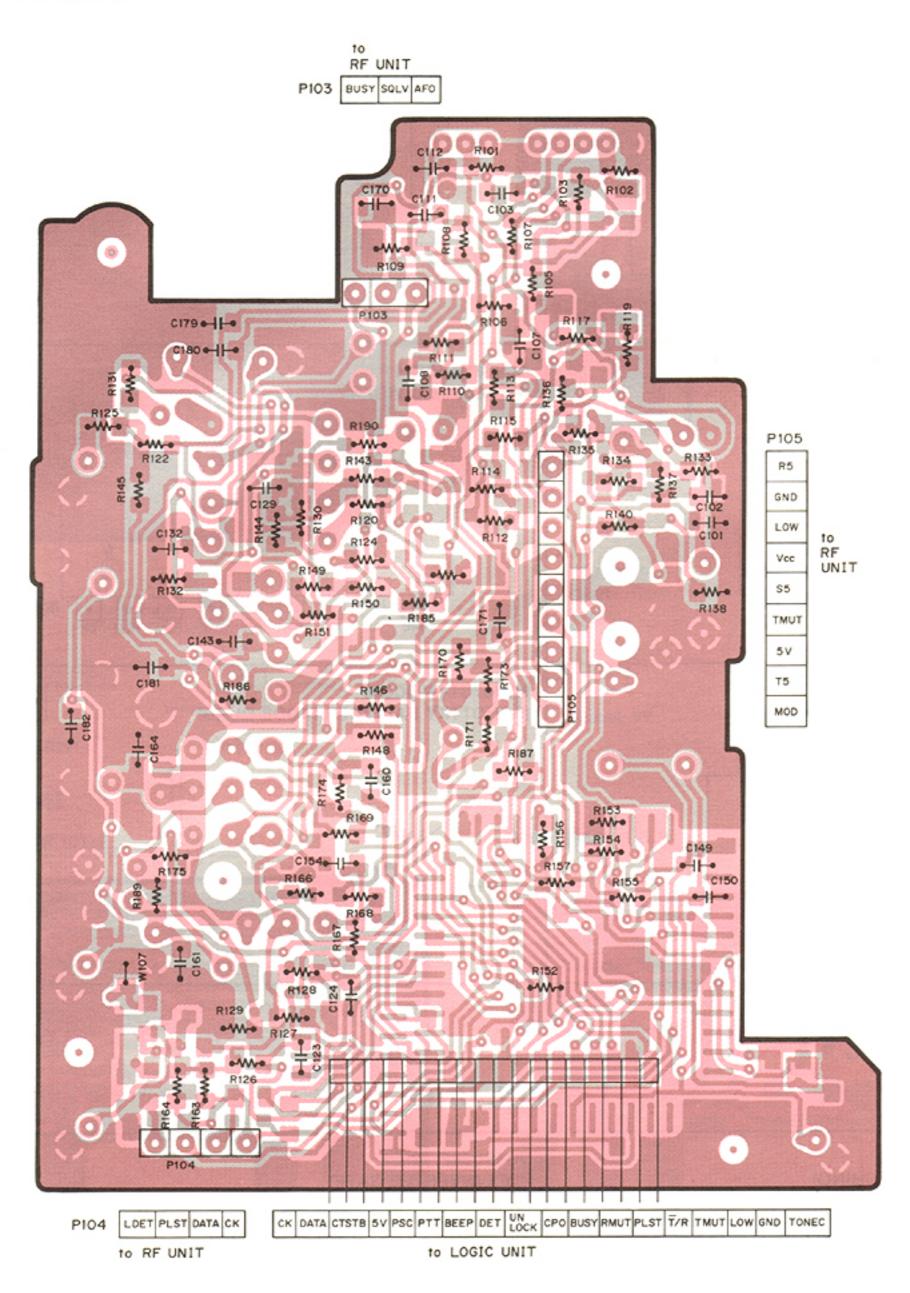


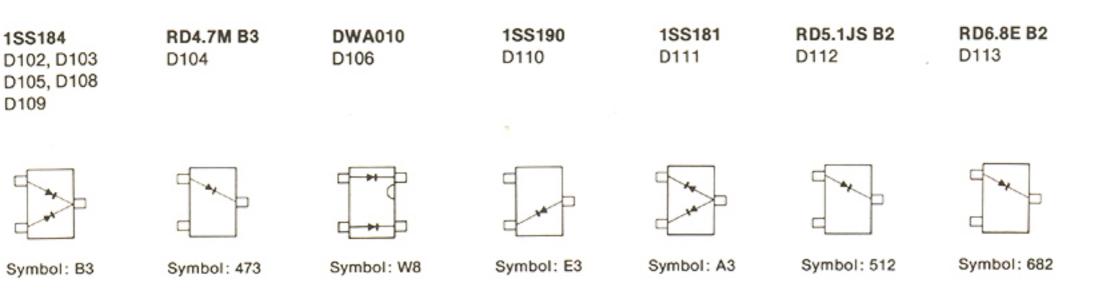
### COMPONENTS SIDE



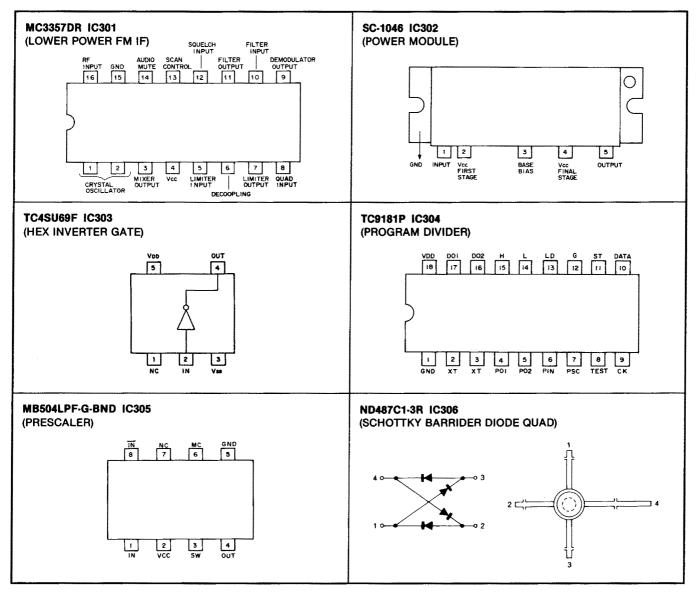


### FOIL SIDE



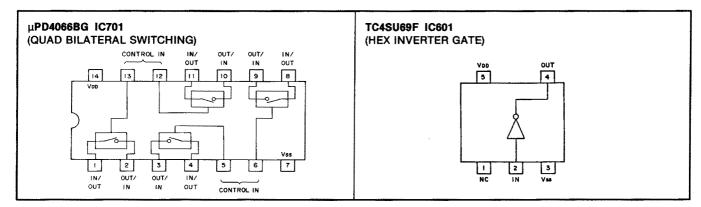


#### 7-4 RF UNIT



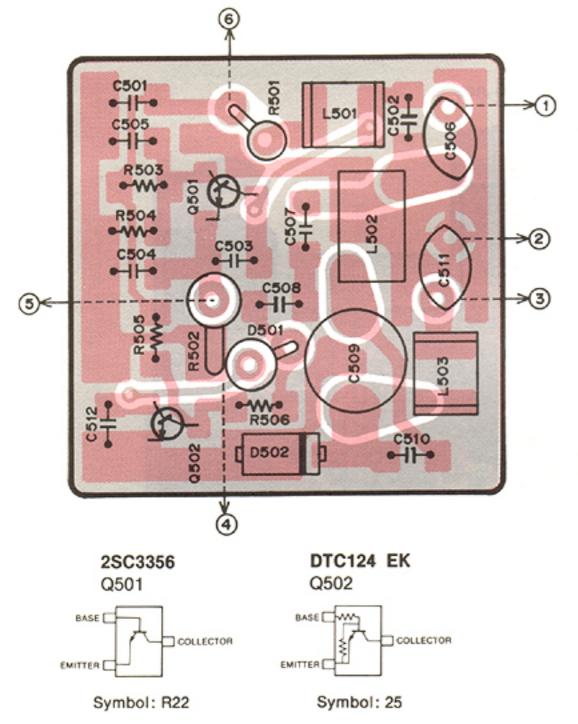
#### **FILTER UNIT**

SQL UNIT

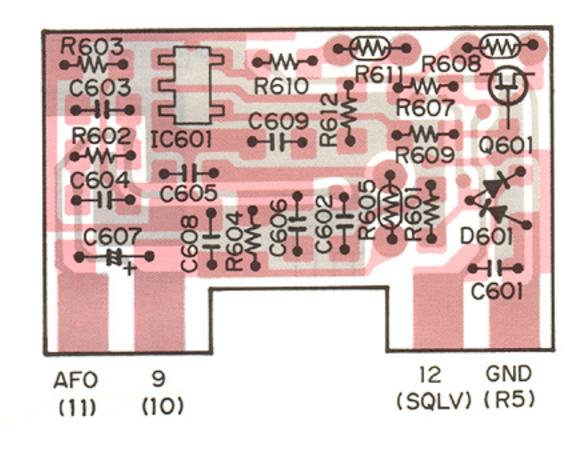


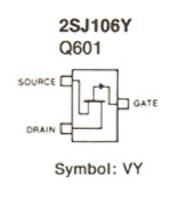
### 7-4 RF UNIT

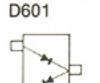
VCO UNIT



### SQL UNIT





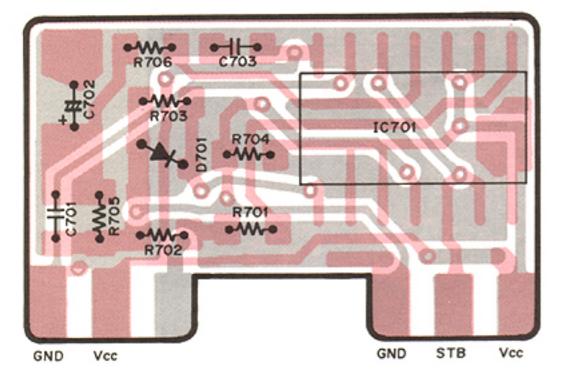


HSM88AS

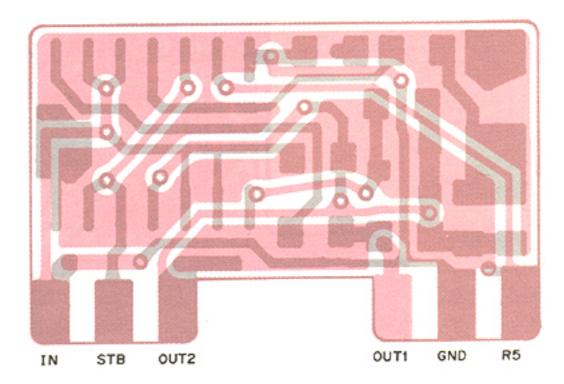
Symbol: C1

# • FILTER UNIT

### COMPONENTS SIDE

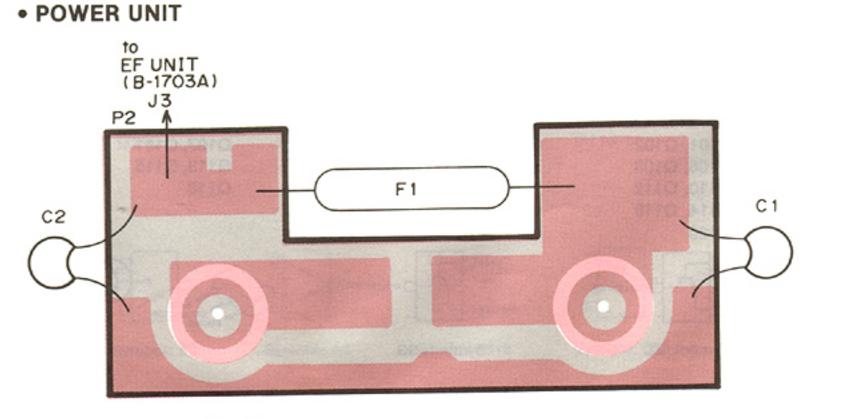


### FOIL SIDE

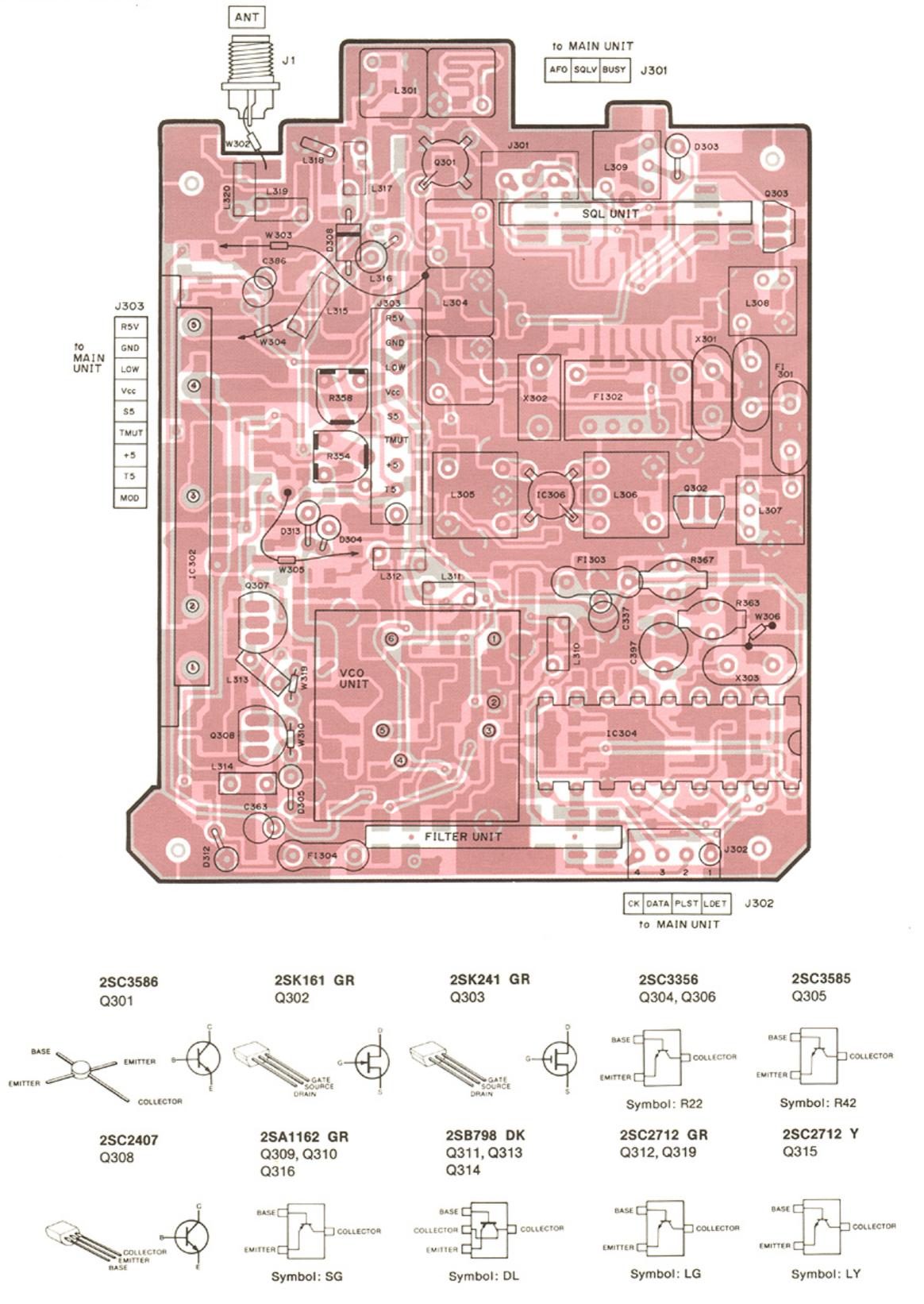


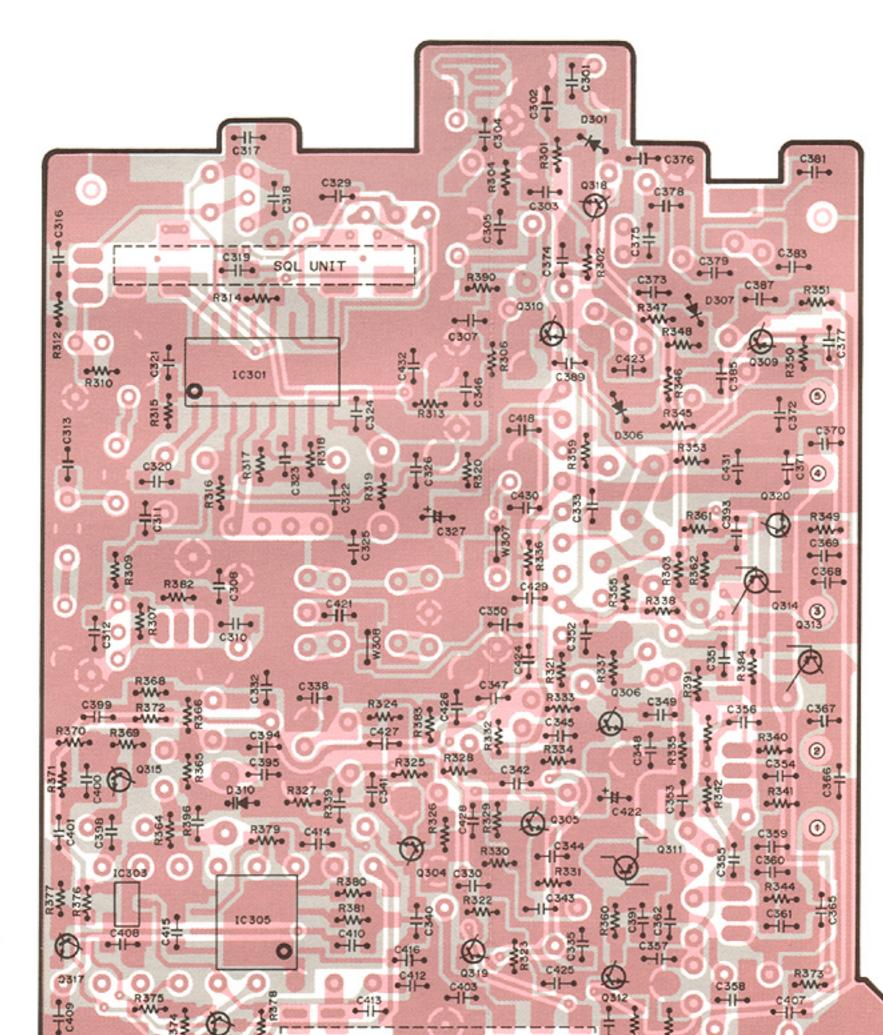
1SS193 D701

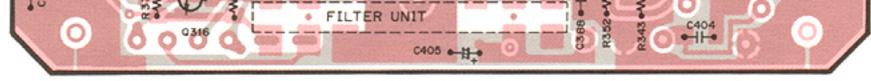
Symbol: F3



#### COMPONENTS SIDE











1SS153 D301





1SS154

D306, D307

Symbol: A9

Symbol: BA

2SC2712 BL Q317, Q318 2SC3395 Q320



### SECTION 8 PARTS LIST

#### [EF UNIT]

REF. NO.	DESCRIPTION	PART NO.	
R1	Variable Resistor	RK0971111	
C1 C2 C4	Ceramic Ceramic Ceramic	47pF 50V 47pF 50V 47pF 50V	
C5	Ceramic	470pF 50V	
J1 J2 J3	Connector Connector Connector	TNC-R107 PI28A04M RT-01-1.0B	
P1 P2	Connector Connector	PI28A04F SMF-01T-1.0	
F1	Fuse	MC2 1/2	
DS1 DS2	LED LED	TLSG222 TLSG222	
MC1	Microphone	KUC-2023-01-006	
S1 S2 S3	Switch Switch Switch	KSR16-0-18 (CHANNEL) MS-243 2P (SCAN) MS-243 2P (MONITOR)	
SP1	Speaker	40P-177B	
EP1 EP2 EP3 EP4		B-1702 B (POWER UNIT) B-1703 A (VOL UNIT) B-1704 B (LED UNIT) B-1705 B (LOGIC-EF)	
W1 W2 W3 W4 W5	Wire Wire Wire Wire	13/02/140/W01/B30 24/04/050/D02/W01 24/01/050/D02/W01 24/03/080/D02/W01 24/00/100/D02/W01	

#### [LOGIC UNIT]

REF. NO.	DESCRIPTION	PART NO.
IC801	IC	μPD75306GF-015-3B9
IC802	IC	S-8054ALB-LM-T
Q801	Transistor	2SC3395
Q802	Transistor	2SA1362 GR
Q803	Transistor	2SC2712 BL *
Q804	Transistor	2SC3395
Q805	Transistor	2SA1162 GR
Q806	Transistor	2SC3395
Q807	Transistor	2SC3395
Q808	Transistor	2SC3395

#### [LOGIC UNIT]

-			
REF. NO.	DESCRIPTION	PART NO.	
Q809 Q810	Transistor Transistor	2SC3395 2SA1341 GR	
D801 D802 D803 D804 D805	Diode Diode Diode Diode Diode	1SS187 1SS190 1SS196 1SS196 1SS184	
X801	Crystal	RF4A3 FAC (4.19MHz)	
R801 R802 R803 R804 R805 R806 R807 R808 R809 R810 R811 R812 R813 R814 R815 R816 R815 R816 R817 R818 R819 R820 R821 R822 R823 R823 R827	Resistor Resistor	47kΩ         MCR10           1MΩ         MCR10           1MΩ         MCR10           47kΩ         MCR10           47kΩ         MCR10           47kΩ         MCR10           47kΩ         MCR10           47kΩ         MCR10           470Ω         MCR10           470Ω         MCR10           470Ω         MCR10           470Ω         MCR10           100kΩ         MCR10           100kΩ         MCR10           1MΩ         MCR10           1KΩ         MCR10           1MΩ         MCR10      <	
R828 R829	Resistor Resistor	1MΩ MCR10 220kΩ MCR10	
C801 C802 C803 C804 C805 C806 C807	Ceramic Tantalum Ceramic Ceramic Ceramic Ceramic Ceramic	0.01µF GRM40 B TESVD0J476M-8L 0.01µF GRM40 B 15pF GRM40 CH 15pF GRM40 CH 0.001µF GRM40 470pF GRM40	
J801	Connector	SLEM12R-2	
S801	Switch	SKHHLB0001 (CLONE)	
BT801	Lithium Battery	BR2032-1HF	
EP801	P.C. Board	B-1664C (LOGIC UNIT)	
W801 W802	Jumper Jumper	MCR10-JPW MCR10-JPW	

## [MAIN UNIT]

## [MAIN UNIT]

REF. NO.	DESCRIPTION	PAR	r no.		REF. NO.	DESCRIPTION	PART	Γ NO.
IC101	IC	BA4558F		1	R131	Resistor	1.8kΩ	MCR10
C102	IC	LM386N-	3		R132	Resistor	150kΩ	MCR10
IC103	IC	μPD4094	3G-T1		R133	Resistor	820Ω	MCR10
IC104	IC	MN6520		1	R134	Resistor	6.8kΩ	MCR10
				1	R135	Resistor	1.5MΩ	MCR10
				1	R136	Resistor	470kΩ	MCR10
Q101	Transistor	2SC2712	BL		R137	Resistor	33kΩ	MCR10
	Transistor	2SC2712			R138	Resistor	1MΩ	MCR10
Q102						Resistor	1MΩ	MCR10
Q103	Transistor	2SA1162			R140	1		MCR10
Q104	Transistor	2SA1162		1	R141	Resistor	1MΩ	
Q105	Transistor	2SA1162		1	R142	Resistor	12kΩ	MCR10
Q106	Transistor	2SC2712	BL		R143	Resistor	330kΩ	MCR10
Q107	Transistor	2SB909M	R		R144	Resistor	12kΩ	MCR10
Q108	Transistor	2SC2712	BL	1	R145	Resistor	1.2kΩ	MCR10
Q109	FET	2SJ106 Y			R146	Resistor	10kΩ	MCR10
Q110	Transistor	2SC2712		1	R147	Resistor	470Ω	MCR10
				1	R148	Resistor	47kΩ	MCR10
Q111	Transistor	2SB909M		1				
Q112	Transistor	2SC2712		1	R149	Resistor	56kΩ	MCR10
Q113	Transistor	2SB909M	R	1	R150	Resistor	47kΩ	MCR10
Q114	Transistor	2SC2712		1	R151	Resistor	1.2kΩ	MCR10
Q115	Transistor	2SB909M		1	R152	Resistor	47kΩ	MCR10
Q116	Transistor	2SA1162		1	R153	Resistor	10kΩ	MCR10
		2SA1162		1	R154	Resistor	8.2kΩ	MCR10
Q117	Transistor			1		1	0.2KΩ 10kΩ	MCR10
Q118	Transistor	2SB909M		1	R155	Resistor		
Q119	Transistor	2SC2712		1	R156	Resistor	150kΩ	MCR10
Q120	Transistor	2SC2712	BL	1	R157	Resistor	2.2kΩ	MCR10
				1	R158	Resistor	10kΩ	MCR10
				1	R159	Resistor	10kΩ	MCR10
D101	Diode	1SS226		1	R160	Trimmer	47kΩ	RH04A3AS4J
D102	Diode	155184			R161	Resistor	1kΩ	MCR10
		1SS184			R163	Resistor	47kΩ	MCR10
D103	Diode			1			47kΩ	MCR10
D104	Zener	RD4.7MB	2	1	R164	Resistor		
D105	Diode	155184			R165	Resistor	15kΩ	MCR10
D106	Diode	DWA010			R166	Resistor	10kΩ	MCR10
D108	Diode	1SS184			R167	Resistor	1kΩ	MCR10
D109	Diode	1SS184			R168	Resistor	4.7kΩ	MCR10
D110	Diode	155190			R169	Resistor	4.7kΩ	MCR10
D111	Diode	1SS180		1	R170	Resistor	10kΩ	MCR10
			<b>D</b> 0	1	1	1	180kΩ	MCR10
D112	Zener	RD5.1JS		1	R171	Resistor		
D113	Zener	RD6.8JE	B2	1	R172	Resistor	33kΩ	MCR10
					R173	Resistor	10kΩ	MCR10
					R174	Resistor	4.7kΩ	MCR10
X101	Crystal	RF4A3 F	AC (4.194MHz)		R175	Resistor	2.7kΩ	MCR10
				1	R183	Resistor	220kΩ	MCR10
				1	R185	Resistor	56kΩ	MCR10
R101	Resistor	33kΩ	MCR10	1	R186	Resistor	4.7kΩ	MCR10
		560Ω	MCR10	1	R187	Resistor	100kΩ	MCR10
R102	Resistor			1				
R103	Resistor	180kΩ	MCR10	1	R188	Resistor	10Ω	MCR10
R104	Trimmer	330kΩ	RH04A3AN5J	1	R189	Resistor	1.5kΩ	MCR10
R105	Resistor	180kΩ	MCR10	1	R190	Resistor	47kΩ	MCR10
R106	Resistor	1kΩ	MCR10	1	R191	Thermistor	33D28	
R107	Resistor	180kΩ	MCR10	1	1			
108	Resistor	120kΩ	MCR10					
R109	Resistor	220kΩ	MCR10	1	C101	Ceramic	47pF	GRM40
R110	Resistor	82kΩ	MCR10	1	C102	Ceramic	0.001µF	GRM40
				1			0.001µF	GRM40 F
R111	Resistor	82kΩ	MCR10	1	C103	Ceramic	•	35V SV
3112	Resistor	1.2kΩ	MCR10	1	C104	Tantalum	0.1µF	
R113	Resistor	3.9kΩ	MCR10	1	C105	Ceramic	470pF	GRM40
R114	Resistor	390kΩ	MCR10		C106	Ceramic	470pF	GRM40
R115	Resistor	1MΩ	MCR10	1	C107	Ceramic	470pF	GRM40
R116	Trimmer	47kΩ	RH04A3AS4J	1	C108	Ceramic	0.001µF	GRM40
3117	Resistor	100kΩ	MCR10		C109	Ceramic	0.0022µF	GRM40
		330kΩ	RH04A3AN5J	1	C110	Ceramic	470pF	GRM40
R118	Trimmer			1			-	
R119	Resistor	390kΩ	MCR10	1	C111	Ceramic	120pF	GRM40 CH
7120	Resistor	27kΩ	MCR10	1	C112	Ceramic	0.001µF	GRM40
7121	Resistor	47kΩ	MCR10	1	C113	Tantalum	2.2µF	TEMSVA1C225M
R122	Resistor	1kΩ	MCR10		C114	Ceramic	0.1µF	GRM40 F
R123	Resistor	47kΩ	MCR10	1	C115	Tantalum	2.2µF	TEMSVA1C225N
R124	Resistor	56kΩ	MCR10	1	C116	Ceramic	0.1µF	GRM40 F
R125	Resistor	1kΩ	MCR10	1	C117	Ceramic	0.1µF	GRM40 F
1				1		Ceramic	0.1μF	GRM40 F
R126	Resistor	27Ω	MCR10	1	C118			
R127	Resistor	5.6kΩ	MCR10	1	C119	Ceramic	0.001µF	GRM40
128	Resistor	47kΩ	MCR10		C120	Ceramic	0.1µF	GRM40 F
129	Resistor	47kΩ	MCR10	1	C121	Ceramic	0.0068µF	GRM40
		1kΩ	MCR10		C122	Ceramic	0.0068µF	GRM40

#### [MAIN UNIT]

REF. NO.	DESCRIPTION	PART	NO.
C123	Ceramic	47pF	GRM40
C124	Ceramic	47pF	GRM40
C125 C126	Ceramic Electrolytic	47pF 100uF	GRM40 6.3V RC3
C126 C127	Electrolytic	10µF	16V RC3
C128	Tantalum	2.2µF	TEMSVA1C225M-8L
C129	Ceramic	470pF	GRM40
-C130	Electrolytic	1μF	50V RC3
C131	Tantalum	1μF 470-5	16V SV
C132 C133	Ceramic Ceramic	470pF 0.1μF	GRM40 GRM40 F
C134	Ceramic	0.0068µF	
C135	Ceramic	0.0047µF	GRM40
C136	Ceramic	0.01µF	GRM40 F
C137	Electrolytic	10µF	16V RC3
C138 C139	Ceramic Ceramic	0.1μF 470pF	GRM40 F GRM40
C139 C140	Ceramic	0.1μF	GRM40 F
C141	Ceramic	470pF	GRM40
C142	Tantalum	0.47µF	TEMSVA1V474M-8L
C143	Ceramic	470pF	GRM40
C144	Electrolytic	10µF	16V RC3
C145	Ceramic	0.001µF 0.1µF	GRM40 GRM40 F
C146 C147	Ceramic Ceramic	0.1μF 0.01μF	GRM40 F
C148	Electrolytic	22µF	16V RC3
C149	Ceramic	18pF	GRM40 CH
C150	Ceramic	18pF	GRM40 CH
C151	Ceramic	470pF	GRM40
C152	Electrolytic	47pF 0.1μF	6.3V RC3 GRM40 F
C153 C154	Ceramic Ceramic	470pF	GRM40
C155	Electrolytic	22µF	16V RC3
C156	Electrolytic	22µF	16V RC3
C158	Electrolytic	22µF	16V RC3
C159	Ceramic	0.001µF	GRM40 GRM40
C160 C161	Ceramic Ceramic	470pF 470pF	GRM40
C161	Electrolytic	22µF	6.3V RC3
C163	Electrolytic	47μF	16V MS5
C164	Ceramic	470pF	GRM40
C165	Tantalum	3.3µF	6.3V SV
C166 C167	Tantalum Ceramic	0.47μF 0.1μF	35V DN GRM40 F
C167	Ceramic	0.0047µF	GRM40
C169	Tantalum	4.7µF	16V DN
C170	Ceramic	470pF	GRM40
C171	Ceramic	0.001µF	
C177	Ceramic	0.001µF	GRM40 GRM40
C179 C180	Ceramic Ceramic	47рҒ 47рҒ	GRM40
C181	Ceramic	47pF	GRM40
C182	Ceramic	47pF	GRM40
1404	0		
J101 J102	Connector Connector	PI28A05M PI28A04M	
J102	Connector	HSJ-1102-	
J104	Connector	HSJ-0836-	
Diat	Connector		
P101	Connector Connector	PI28A04F BB04A03F	-
P103 P104	Connector	BB04A03F	
P104	Connector	BB04A09F	
S101	Switch	SKHHLPO	00 (PTT)
			*
EP101	P.C. Board		MAIN UNIT)
EP104	F.P.C.	•	OGIC-MAIN)
EP106	Ferrite Bead	DL-20P2.6	
EP108	Ferrite Bead	DL-20P2.6	-3-1.ZT

#### [MAIN UNIT]

REF. NO.	DESCRIPTION	PART NO.	
W101	Wire	24/03/040/D02/C21	
W102	Wire	24/01/055/D02/C21	
W103	Wire	23/02/065/D02/C21	
W104	Wire	23/00/030/D02/C21	
W105	Jumper	MCR10-JPW	
W106	Jumper	MCR10-JPW	
W107	Jumper	MCR10-JPW	
W108	Jumper	MCR10-JPW	

## [RF UNIT]

REF. NO.	DESCRIPTION	PART NO.
IC301	IC	MC3357 DR
IC302	IC	SC-1055
1C303	IC	TC4SU69F
IC304	IC	TC9181P
1C305	IC	MB504LPF-G-BND
1C306	Array	ND487C1-3R
Q301	Transistor	2SC3586
Q302	FET	2SK161 GR
Q303	FET	2SK241 GR
Q304	Transistor	2SC3356
Q305	Transistor	2SC3585
Q306	Transistor	2SC3356
Q307	Transistor	2SC2026
Q308	Transistor	2SC2407
Q309	Transistor	2SA1162 GR
	Transistor	2SA1162 GR
Q310		
Q311	Transistor	2SB798 DK
Q312	Transistor	2SC2712 GR
Q313	Transistor	2SB798 DK
Q314	Transistor	2SB798 DK
Q315	Transistor	2SC2712 Y
Q316	Transistor	2SA1162 GR
Q317	Transistor	2SC2712 BL
Q318	Transistor	2SC2712 BL
Q319	Transistor	2SC2712 GR
Q320	Transistor	2SC3395
D301	Diode	1SS153
D303	Diode	15597
D304	Diode	1SS265
D305	Diode	1SS254
D306	Diode	1SS154
D307	Diode	1SS154
D308	Diode	1SS265
D310	Varicap	1SV166
D312	Zener	RD6.2JS B2
D313	Diode	1SS265
FI301	Crystal	FL-79
FI302	Ceramic	CFZM455E10
FI303	LC	EXC-EMT-103DC
FI304	LC	EXC-EMT-103DC
X301	Crystal	CR188 (22.695MHz)
X302	Ceralock	CDB455 C7A
X303	Crystal	CR212 (10MHz)
		61 1147 <i>4 45 45</i> 4
L301	Herical	5HW-44545A
L304	Herical	05M-3075
L305	Coll	LR-145

## [RF UNIT]

# [RF UNIT]

REF. NO.	DESCRIPTION	PAR	IT NO.	REF. NO.	
L306	Coll	LR-145		R364	F
L307	Coil	LS-330		R365	F
L308	Coil	LS-332		R366	F
L309	Coll	LS-331		R367	
L310 L311	Coil	LA-232 LA-232		R368 R369	
L312	Coil	LA-232		R370	F
L313	Coil	LA-126		R371	F
L314	Coll	LA-126		R372	F
L315	Coll	LA-232		R373	R
L316	Choke	LAL02TA	R56M	R374	F
L317	Coil	LA-232		R375	F
L318	Coil	LA-222		R376	R
L319 L320	Coil Coil	LA-232 LA-232		R377 R378	
1320		LACEDE		R379	
				R380	R
R301	Resistor	330Ω	MCR10	R381	R
R302	Resistor	1ΜΩ	MCR10	R382	R
R303	Resistor	47kΩ	MCR10	R383	R
R304	Resistor	22kΩ	MCR10	R384	R
R306	Resistor	22Ω	MCR10	R390	R
R307	Resistor	6.8kΩ	MCR10	R391	R
R309 R310	Resistor Resistor	22Ω 10kΩ	MCR10 MCR10		
R312	Resistor	100Ω	MCR10	C301	c
R313	Resistor	47Ω	MCR10	C302	lõ
R314	Resistor	10kΩ	MCR10	C303	c
R315	Resistor	47kΩ	MCR10	C304	C
R316	Resistor	1.5kΩ	MCR10	C305	C
R317	Resistor	1.5kΩ	MCR10	C307	C
R318	Resistor	47kΩ	MCR10	C308	C
R319 R320	Resistor	1.5kΩ 100Ω	MCR10	C310	
R320 R321	Resistor Resistor	22kΩ	MCR10 MCR10	C311 C312	
R322	Resistor	10kΩ	MCR10	C313	l č
R323	Resistor	100kΩ	MCR10	C316	C C
R324	Resistor	100Ω	MCR10	C317	c
R325	Resistor	47kΩ	MCR10	C318	C
R326	Resistor	10kΩ	MCR10	C319	C
R327	Resistor	10Ω	MCR10	C320	
R328 R329	Resistor	100Ω 22kΩ	MCR10	C321	
R329	Resistor Resistor	22K12 5.6kΩ	MCR10 MCR10	C322 C323	
R331	Resistor	10Ω	MCR10	C324	c
R332	Resistor	47Ω	MCR10	C325	C
R333	Resistor	15kΩ	MCR10	C326	C
R334	Resistor	4.7kΩ	MCR10	C327	Ta
R335	Resistor	10Ω	MCR10	C329	C
R336	Resistor	10kΩ	MCR10	C330	C
R337 R338	Resistor Resistor	22kΩ 10kΩ	MCR10 MCR10	C332 C333	
R339	Resistor	1.2kΩ	MCR10	C335	
R340	Resistor	560Ω	MCR10	C337	Та
R341	Resistor	22Ω	MCR10	C338	C
R342	Resistor	1kΩ	MCR10	C339	C
R343	Resistor	220Ω	MCR10	C340	C
R344	Resistor	10Ω	MCR10	C341	Ce
R345	Resistor	6.8kΩ	MCR10	C342	Ce
R346	Resistor	470Ω	MCR10	C343	C
R347 R348	Resistor Resistor	6.8kΩ 470Ω	MCR10 MCR10	C344 C345	Ce Ce
R349	Resistor	82kΩ	MCR10	C346	Ce
R350	Resistor	22kΩ	MCR10	C347	Ce
R351	Resistor	150kΩ	MCR10	C348	Ce
R352	Resistor	560kΩ	MCR10	C349	Ce
R353	Resistor	22kΩ	MCR10	C350	Ce
R354	Trimmer	100kΩ	RH0421CJ15J06A	C351	Ce
R355	Resistor	6.8kΩ	MCR10	C352	Ce
R358	Trimmer	33kΩ 1kΩ	RH0421CN4J02A	C353	Ce
R359 R360	Resistor Resistor	1κΩ 4.7kΩ	MCR10 MCR10	C354 C355	Ce Ce
R361	Resistor	6.8kΩ	MCR10	C356	Ce
R362	Resistor	6.8kΩ	MCR10	C357	Ce

F. NO.	. NO. DESCRIPTION		RT NO.			
364	Resistor	15kΩ	MCR10			
365	Resistor	10kΩ	MCR10			
366	Resistor	10kΩ	MCR10			
367 368	Thermistor Resistor	6.8kΩ	33D28 MCR10			
369	Resistor	100kΩ	MCR10			
370	Resistor	100kΩ	MCR10			
371	Resistor	2.2kΩ	MCR10			
372	Resistor	100Ω	MCR10			
373 374	Resistor Resistor	1.8kΩ 12kΩ	MCR10 MCR10			
875	Resistor	39kΩ	MCR10			
376	Resistor	12kΩ	MCR10			
377	Resistor	12kΩ	MCR10			
378	Resistor	4.7kΩ	MCR10			
379 190	Resistor	10kΩ	MCR10			
180 181	Resistor Resistor	1kΩ 33kΩ	MCR10 MCR10			
82	Resistor	47kΩ	MCR10			
83	Resistor	100Ω	MCR10			
84	Resistor	10kΩ	MCR10			
90	Resistor	1kΩ	MCR10			
191	Resistor	220Ω	MCR10			
01	Ceramic	47pF	GRM40			
02	Ceramic	43pF	GRM40 CH			
03	Ceramic	47p	GRM40			
04	Ceramic	47pF	GRM40			
05	Ceramic	470pF	GRM40 GRM40			
07 08	Ceramic Ceramic	0.001µF 120pF	GRM40 GRM40			
10	Ceramic	0.001µF	GRM40			
11	Ceramic	0.001µF	GRM40			
12	Ceramic	0.1µF	GRM40 F			
13	Ceramic	5pF	GRM40 GRM40 E			
16	Ceramic	0.1µF	GRM40 F GRM40 F			
17 18	Ceramic Ceramic	0.1µF 33pF	GRM40 r GRM40			
19	Ceramic	0.001µF	GRM40			
20	Ceramic	27pF	GRM40			
21	Ceramic	27pF	GRM40			
22	Ceramic	0.022μF	GRM40 GRM40 F			
23 24	Ceramic Ceramic	0.1µF 82pF	GRM40 F GRM40			
25	Ceramic	0.1µF	GRM40 F			
26	Ceramic	470pF	GRM40			
27	Tantalum	4.7µF	TESVB0J475M-12L			
29	Ceramic	47pF	GRM40			
30 32	Ceramic Ceramic	0.001μF 0.001μF	GRM40 GRM40			
33	Ceramic	0.001µF	GRM40 GRM40			
35	Ceramic	470pF	GRM40			
37	Tantalum	4.7µF	10V DN			
38	Ceramic	470pF	GRM40			
39 40	Ceramic	470pF 6pF	GRM40 GRM40			
40 41	Ceramic Ceramic	өрг 470рF	GRM40 GRM40			
42	Ceramic	470pr 47pF	GRM40 GRM40			
43	Ceramic	0.5pF	GRM40			
44	Ceramic	47pF	GRM40			
45	Ceramic	4pF	GRM40			
46 47	Ceramic Ceramic	470pF 470pF	GRM40 GRM40			
48	Ceramic	470pF 470pF	GRM40 GRM40			
49	Ceramic	12pF	GRM40			
50	Ceramic	27pF	GRM40			
51	Ceramic	0.001µF	GRM40			
52	Ceramic	470pF	GRM40			
53   54	Ceramic Ceramic	470pF 470pF	GRM40 GRM40			
55	Ceramic	6pF	GRM40			
56	Ceramic	470pF	GRM40			
57	Ceramic	470pF	GRM40			
58	Ceramic	470pF	GRM40			

## [RF UNIT]

REF. NO.	DESCRIPTION	PAR	T NO.
C359	Ceramic	470pF	GRM40
C360	Ceramic	470pF	GRM40
C361 C362	Ceramic Ceramic	470pF 0.001uF	GRM40 GRM40
C363	Tantalum	10µF	16V DN
C365	Ceramic	6pF	GRM40
C366	Ceramic	470pF	GRM40
C367 C368	Ceramic	47pF	GRM40
C369	Ceramic	470pF 0.001μF	GRM40 GRM40
C370	Ceramic	470pF	GRM40
C371	Ceramic	0.001µF	GRM40
C372 C373	Ceramic Ceramic	6pF 6pF	GRM40 GRM40
C374	Ceramic	470pF	GRM40
C375	Ceramic	7pF	GRM40
C376	Ceramic	6pF	GRM40
C377 C378	Ceramic Ceramic	470pF 10pF	GRM40 GRM40
C379	Ceramic	3pF	GRM40
C381	Ceramic	10pF	GRM40
C383	Ceramic	5pF	GRM40
C385 C386	Ceramic Tantalum	47рF 1.5µF	GRM40 25V DN
C387	Ceramic	470pF	GRM40
C388	Ceramic	470pF	GRM40
C389	Ceramic	47pF	GRM40
C391 C393	Ceramic Ceramic	0.001μF 47ο5	GRM40 GRM40
C393 C394	Ceramic	47pF 0.001μF	GRM40 GRM40
C395	Ceramic	4pF	GRM40 CH
C396	Ceramic	39pF	GRM40 CH
C397 C398	Trimmer	10pF	ECRGA010D30
C398	Ceramic Ceramic	0.001μF 0.1μF	GRM40 GRM40 F
C400	Ceramic	220pF	GRM40
C401	Ceramic	100pF	GRM40
C403	Ceramic	0.022µF	GRM40
C404 C405	Ceramic Tantalum	0.1μF 1μF	GRM40 F 16V SV
C407	Ceramic	470pF	GRM40
C408	Ceramic	0.1µF	GRM40 F
C409 C410	Ceramic Ceramic	0.1μF 0.1μF	GRM40 F GRM40 F
C411	Ceramic	47pF	GRM40
C412	Ceramic	47pF	GRM40
C413	Ceramic	47pF	GRM40
C414 C415	Ceramic Ceramic	0.001μF 0.001μF	GRM40 GRM40
C416	Ceramic	5pF	GRM40
C418	Ceramic	470pF	GRM40
C421	Ceramic	27pF	GRM40
C422 C423	Tantalum Ceramic	6.8µF 470pF	6.3V SV GRM40
C424	Ceramic	470pF	GRM40
C425	Ceramic	470pF	GRM40
C426 C427	Ceramic Ceramic	0.001μF 47pF	GRM40 GRM40
C427 C428	Ceramic	47pF 47pF	GRM40 GRM40
C429	Ceramic	0.001µF	GRM40
C430	Ceramic	0.001µF	GRM40
C431 C432	Ceramic Ceramic	0.1μF 470pF	GRM40 F GRM40
0702	Coramity	-10pr	
	-		_
J301	Connector	BB04J03N	
J302 J303	Connector Connector	BB04J04M BB04J09M	
5000	Connector	200400314	•
			·
EP301 EP302	P.C. Board Ferrite Beads	B-1583D ( DL-20P2.6-	
EP302 EP303	Ferrite Beads	DL-20P2.6	

## [RF UNIT]

REF. NO.	DESCRIPTION	PART NO.	
W302	Jumper	JPW-01A	
W303	Jumper	JPW02A	
W304	Jumper	JPW02A	
W305	Jumper	JPW-02A	
W306	Jumper	JPW-02A	
W307	Jumper	MCR10-JPW	
W308	Jumper	MCR10-JPW	
W309	Jumper	72/98/020/X98/X98	
W310	Jumper	72/98/020/X98/X98	

#### [VCO UNIT]

	REF. NO.	DESCRIPTION	PAR	T NO.
	Q501	Transistor	2SC3356	
	Q502	Transistor	DTC124	EK
			100005	
	D501	Diode	1SS265 MA333	
	D502	Varicap	MASSS	
	L501	Coil	LQH3N1F	ROM
	L502	Coll	LA-234	
	L503	Coll	LQH3N4F	R7M
	R501	Resistor	150Ω	ELR20
	R502	Resistor	220Ω	ELR20
ŀ	R503	Resistor	6.8kΩ	MCR10
	R504	Resistor	4.7kΩ	MCR10
	R505	Resistor	47kΩ	MCR10
	R506	Resistor	4.7kΩ	MCR10
1	C501	Ceramic	470pF	GRM40
	C502	Ceramic	5pF	GRM40 CH
I	C503	Ceramic	8pF	GRM40 CH
	C504	Ceramic	6pF	GRM40 CH
	C505	Ceramic	470pF	GRM40
	C506	Ceramic	0.5pF	50V
	C507 C508	Ceramic Ceramic	5pF 6pF	GRM40 CH GRM40 CH
1	C509	Trimmer	3pF	ECRGA003A30
	C510	Ceramic	4pF	GRM40 CH
I	C511	Ceramic	470pF	50V
	C512	Ceramic	470pF	GRM40
I				
	EP501	P.C. Board	B-1588B (	VCO UNIT)
I				
ł				
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I				
I	1			
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I				
I				
I				
E				

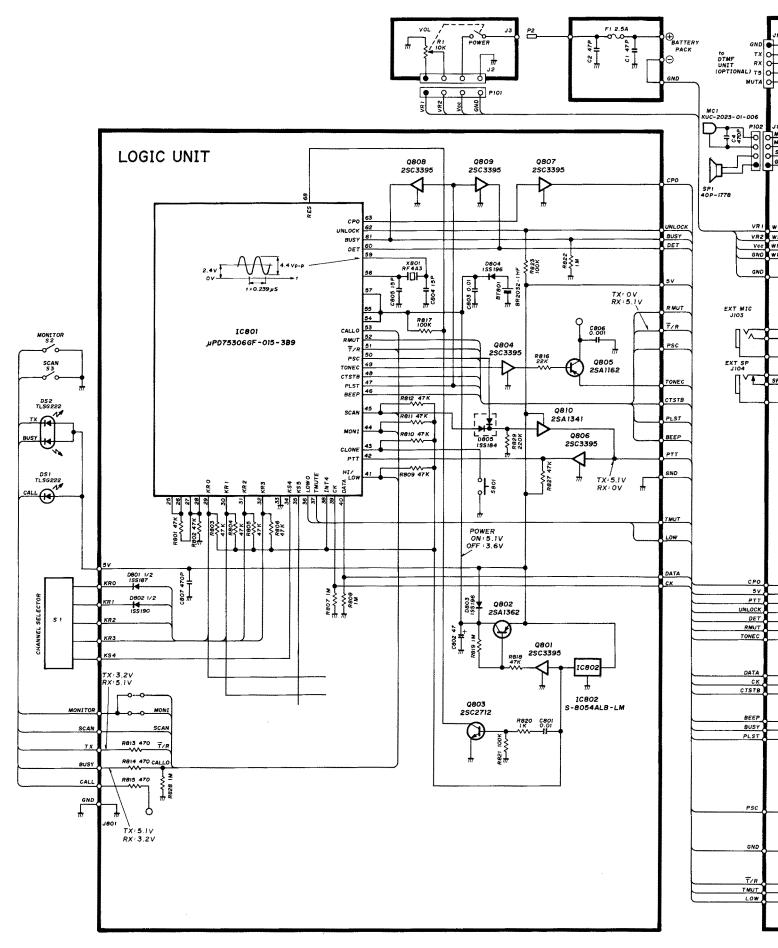
## [SQL UNIT]

REF. NO.	DESCRIPTION	PART	NO.
IC601	IC	TC4SU69F	
Q601	Transistor	2SJ106Y	
D601	Diode	HSM88AS	
R601 R602 R603 R604 R605 R607 R608 R610 R611 R612 C601 C602 C603 C604 C605 C606 C607 C608 C609 EP601	Resistor Resistor Resistor Thermistor Resistor Thermistor Resistor Thermistor Resistor Ceramic	1kΩ 330kΩ 2.2kΩ 33D28 47kΩ 33D28 1MΩ 4.7kΩ 33D28 12kΩ 0.01μF 0.01μF 0.01μF 0.001μF 0.001μF 0.001μF 0.001μF 0.001μF 0.001μF	MCR10 MCR10 MCR10 MCR10 MCR10 MCR10 MCR10 MCR10 MCR10 GRM40

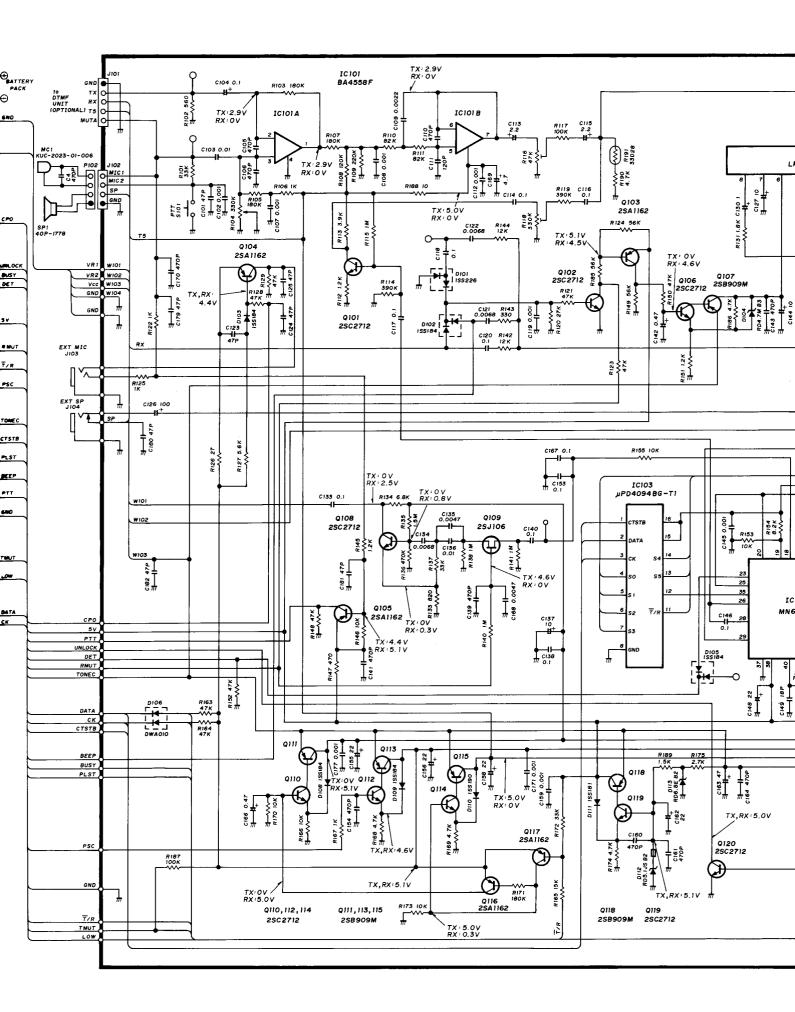
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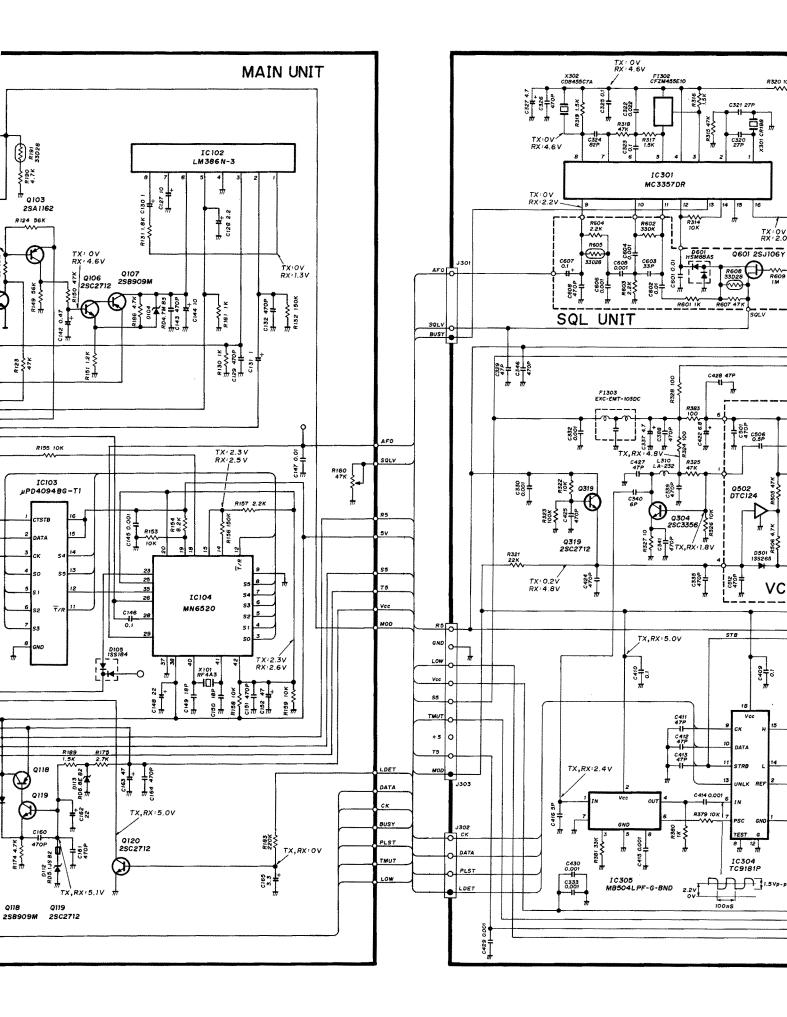
REF. NO.	DESCRIPTION	PAR	Г NO.
IC701	IC	µPD4066	BG
D701	Diode	1SS193	
R701 R702	Resistor Resistor	4.7kΩ 4.7kΩ	MCR10 MCR10
R703	Resistor	10kΩ	MCR10
R704	Resistor	10kΩ	MCR10
R705	Resistor	3.3kΩ	MCR10
R706	Resistor	1kΩ	MCR10
C701 C702 C703	Ceramic Tantalum Ceramic	0.1μF 2.2 0.1μF	GRM40 F 16V SV GRM40 F
EP701	P.C. Board	B-1596B	(FILTER UNIT)

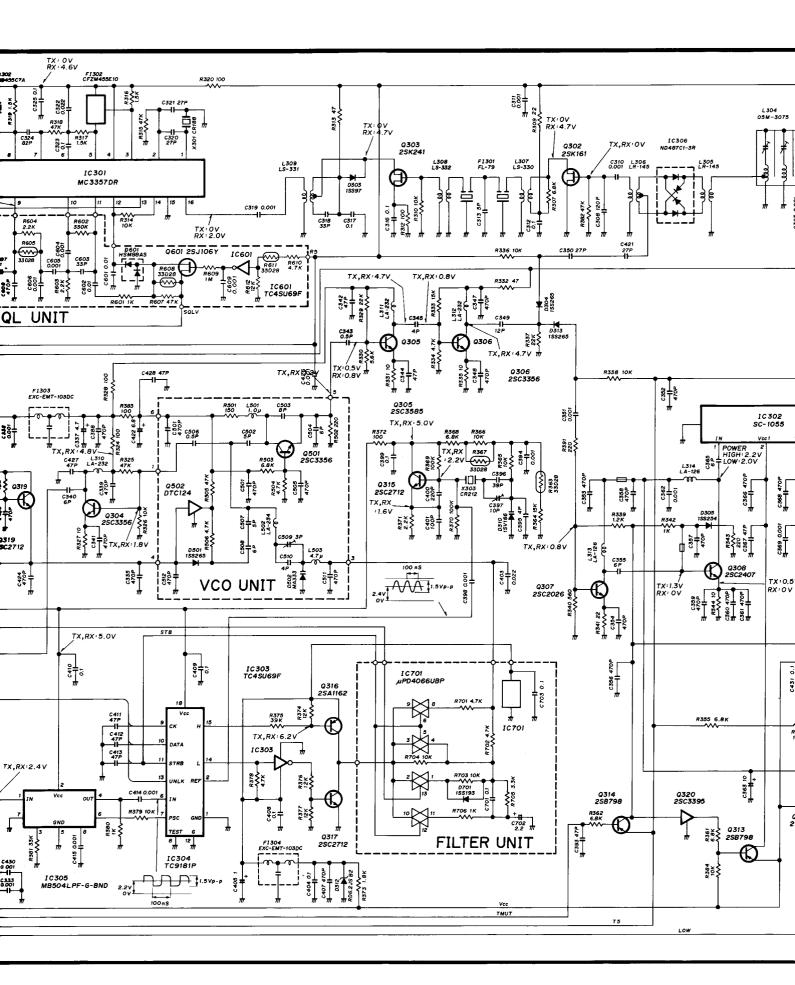
# SECTION 9 VOLTAGE DIAGRAM

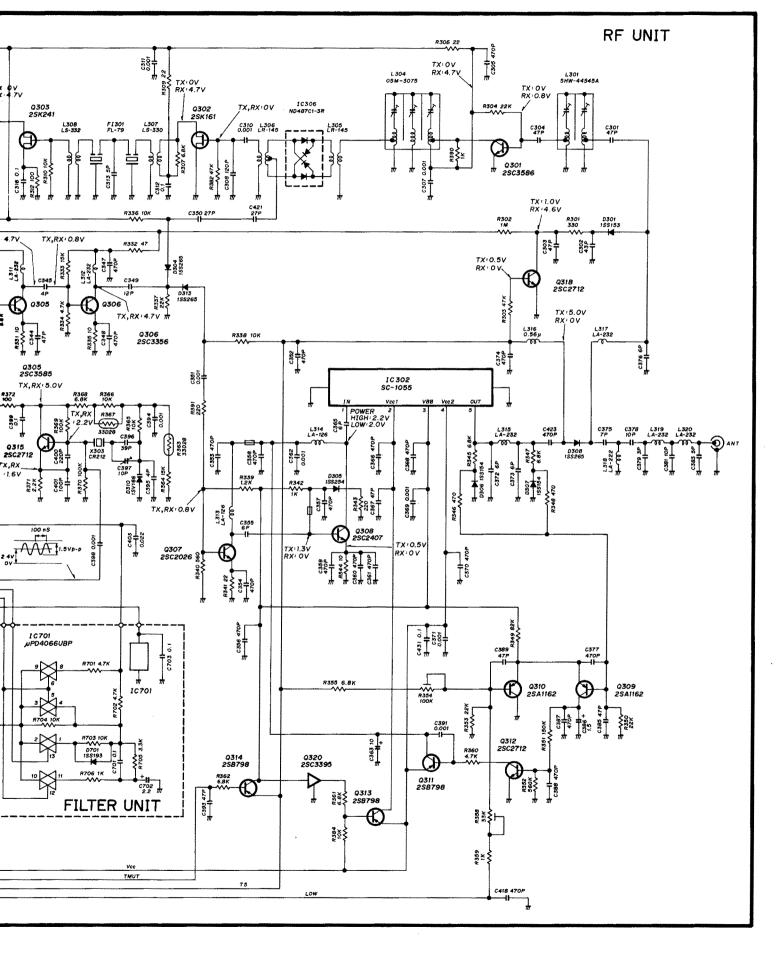


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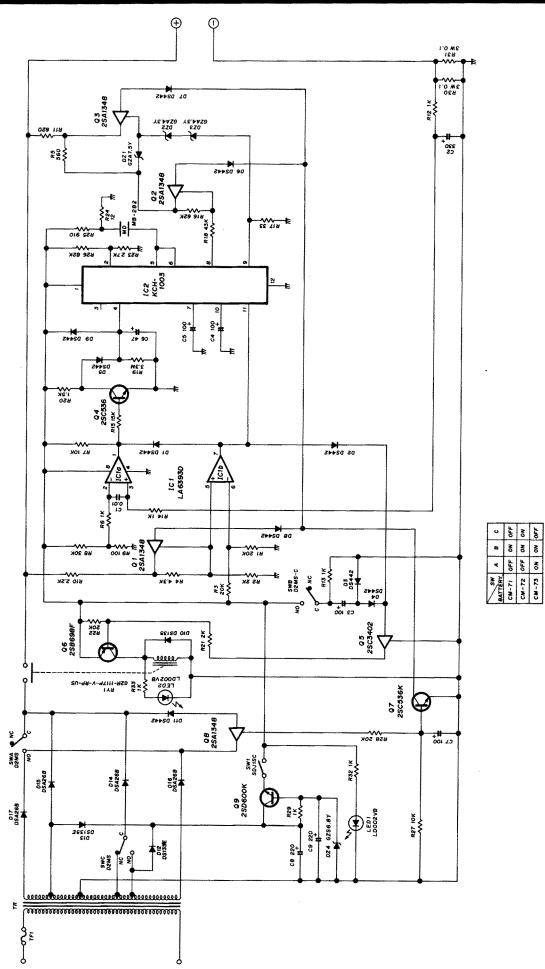






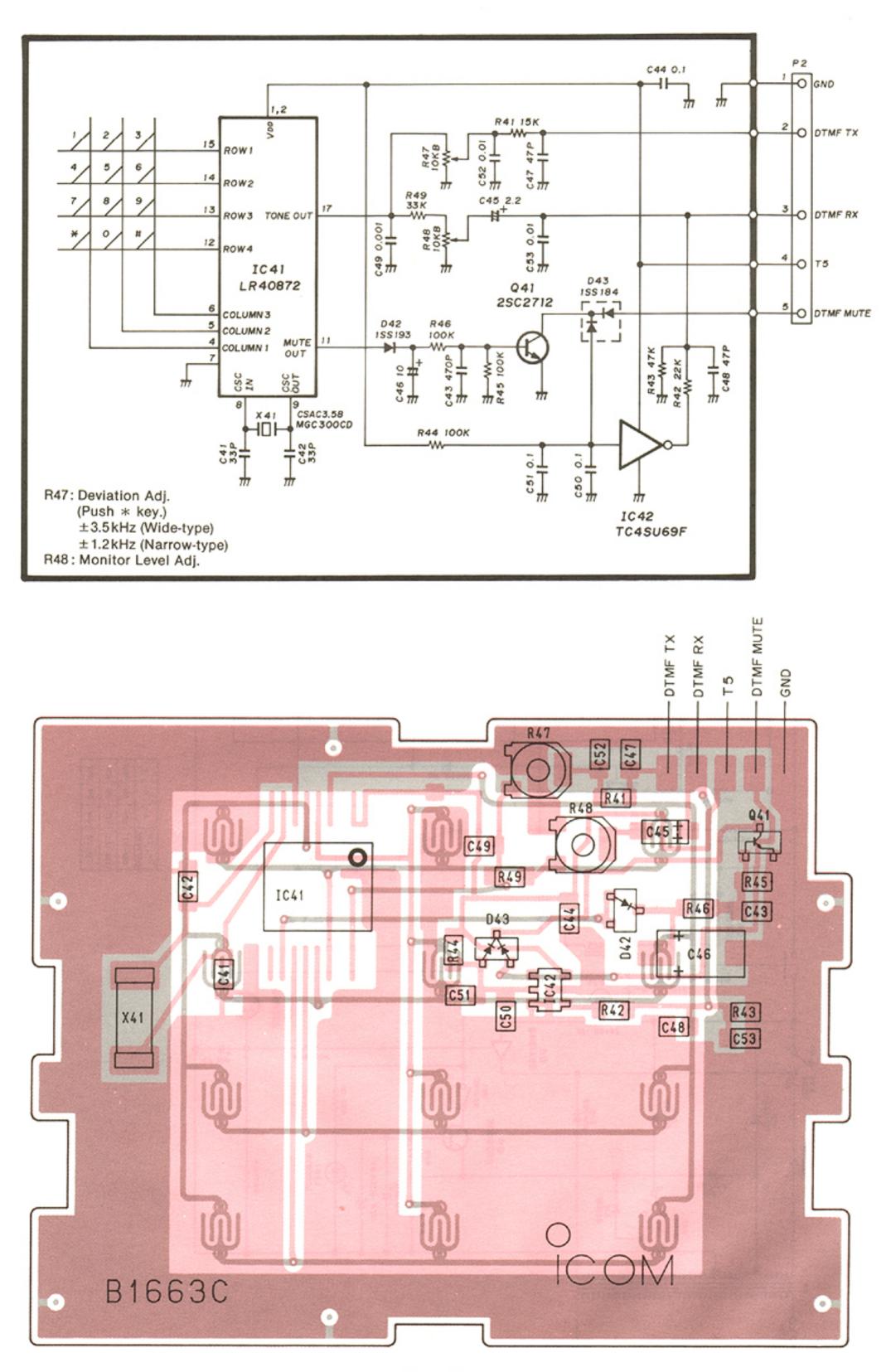
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# SECTION 10 BM-70 SCHEMATIC DIAGRAM



10 - 1

# **UT-42 DTMF ENCODER UNIT**



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